采用 QFN 封装且具有 4.5V 至 14.5V 输入的 LMZ31506H 6A 电源模块

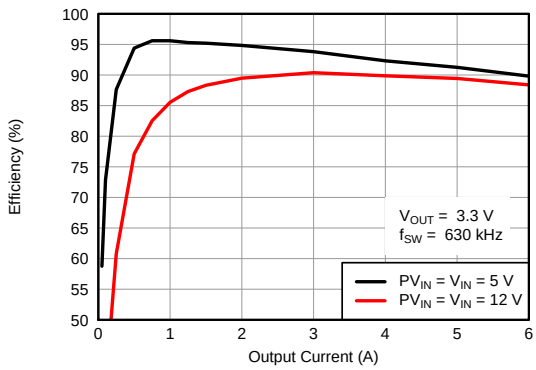
1 特性

- 完整的集成式电源解决方案可实现小尺寸和扁平设计
- 9mm × 15mm × 2.8mm 封装
- 效率高达 96%
- 宽输出电压调节范围 1.2V 至 5.5V，基准精度为 1%
- 可选分离电源轨支持低至 1.7V 的输入电压
- 可调开关频率（480kHz 至 780kHz）
- 与外部时钟同步
- 可调慢速启动
- 输出电压排序和跟踪
- 电源正常输出
- 可编程欠压锁定 (UVLO)
- 输出过流保护
- 过热保护
- 预偏置输出启动
- 工作温度范围：-40°C 至 +85°C
- 增强的热性能：13°C/W
- 符合 EN55022 B 类辐射标准 - 集成屏蔽电感器
- 使用 LMZ31506H 并借助 WEBENCH® 电源设计器创建定制设计方案

2 应用

- 宽带和通信基础设施
- 自动化测试和医疗设备
- 紧凑型 PCI/PCI 快速接口/PXI 快速接口
- DSP 和 FPGA 负载点 应用
- 高密度分布式电源系统

效率



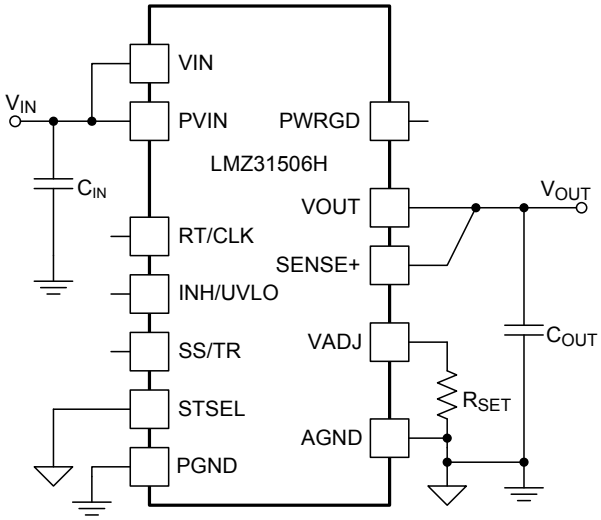
3 说明

LMZ31506H 电源模块是一款易于使用的集成式电源解决方案，它在一个扁平的 QFN 封装内整合了一个带有功率 MOSFET 的 6A 直流/直流转换器、一个屏蔽式电感器和多个无源器件。此整体电源解决方案仅需 3 个外部组件，并省去了环路补偿和磁性元件选择过程。

9mm × 15mm × 2.8 mm QFN 封装能轻松焊接到印刷电路板上，并且可实现效率高于 90% 的紧凑型负载点设计以及结至环境的热阻抗仅为 13°C/W 的出色功率耗散。在环境温度为 85°C 且无气流的情况下，该器件可提供 6A 的满额输出电流。

LMZ31506H 提供了分离式负载点设计的灵活性和特性集，非常适合为高性能 DSP 和 FPGA 供电。先进的封装技术可提供一个与标准 QFN 贴装和测试技术兼容的耐用且可靠的电源解决方案。

简化应用



3.1 Absolute Maximum Ratings(1)

over operating temperature range (unless otherwise noted)

		VALUE	UNIT
Input Voltage	VIN	–0.3 to 16	V
	PVIN	–0.3 to 16	V
	INH/UVLO	–0.3 to 6	V
	VADJ	–0.3 to 3	V
	PWRGD	–0.3 to 6	V
	SS/TR	–0.3 to 3	V
	STSEL	–0.3 to 3	V
	RT/CLK	–0.3 to 6	V
Output Voltage	PH	–1 to 20	V
	PH 10ns Transient	–3 to 20	V
V_{DIFF} (GND to exposed thermal pad)		–0.2 to 0.2	V
Source Current	RT/CLK	±100	µA
	PH	Current Limit	A
Sink Current	PH	Current Limit	A
	PVIN	Current Limit	A
	PWRGD	–0.1 to 5	mA
Operating Junction Temperature		–40 to 125(2)	°C
Storage Temperature		–65 to 150	°C
Peak Reflow Case Temperature(3)		245(4)	°C
Maximum Number of Reflows Allowed(3)		3(4)	
Mechanical Shock	Mil-STD-883D, Method 2002.3, 1 msec, 1/2 sine, mounted	1500	G
Mechanical Vibration	Mil-STD-883D, Method 2007.2, 20-2000Hz	20	

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) See the temperature derating curves in the *Typical Characteristics* section for thermal information.
(3) For soldering specifications, refer to the *Soldering Requirements for BQFN Packages* application note.
(4) Devices with a date code prior to week 14 2018 (1814) have a peak reflow case temperature of 240°C with a maximum of one reflow

3.2 Thermal Information

THERMAL METRIC(1)		LMZ31506H RUQ47 47 PINS	UNIT
θ_{JA}	Junction-to-ambient thermal resistance(2)	13	°C/W
θ_{JCtop}	Junction-to-case (top) thermal resistance(3)	9	
θ_{JB}	Junction-to-board thermal resistance(4)	6	
ψ_{JT}	Junction-to-top characterization parameter(5)	2.5	
ψ_{JB}	Junction-to-board characterization parameter(6)	5	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance(7)	3.8	

(1) 有关传统和新热指标的更多信息，请参见应用报告《*半导体和 IC 封装热指标*》（文献编号：SPRA953）。
(2) 在 JESD51-2a 描述的环境中，按照 JESD51-7 的规定，在一个 JEDEC 标准高 K 电路板上进行仿真，从而获得自然对流条件下的结至环境热阻抗。
(3) 通过在封装顶部进行冷板测试仿真来获得结至外壳（顶部）热阻。JEDEC 标准中没有相关测试的描述，但 可在 ANSI SEMI 标准 G30 - 88 中找到相应的说明。
(4) 结至板热阻，可按照 JESD51-8 中的说明在使用环形冷板夹具来控制 PCB 温度的环境中进行仿真来获得。
(5) 结点至顶部特性参数 ψ_{JT} 估算器件在实际系统中的结温，可通过 JESD51-2a（第 6 节和第 7 节）介绍的步骤从获得 $R_{\theta JA}$ 的仿真数据中获取该温度。
(6) 结点至电路板特性参数 ψ_{JB} 估算器件在实际系统中的结温，可通过 JESD51-2a（第 6 节和第 7 节）介绍的步骤从获得 $R_{\theta JA}$ 的仿真数据中获取该温度。
(7) 通过在外露（电源）焊盘上进行冷板测试仿真来获得结至外壳（底部）热阻。JEDEC 标准中没有相关测试的描述，但 可在 ANSI SEMI 标准 G30 - 88 中找到相应的说明。

3.3 Package Specifications

LMZ31506H		UNIT
Weight		1.26 grams
Flammability	Meets UL 94 V-O	
MTBF Calculated reliability	Per Bellcore TR-332, 50% stress, T_A = 40°C, ground benign	33.9 MHrs

3.4 Electrical Characteristics

over -40°C to 85°C free-air temperature, PVIN = VIN = 12 V, V_{OUT} = 1.8 V, I_{OUT} = 6A,
C_{IN1} = 2 × 22-µF ceramic, C_{IN2} = 68 µF poly-tantalum, C_{OUT1} = 4 × 47-µF ceramic (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
I_{OUT}	Output current	T_A = 85°C, natural convection			0		6	A
VIN	Input bias voltage range	Over I_{OUT} range			4.5		14.5	V
PVIN	Input switching voltage range	Over I_{OUT} range			1.7 (1)		14.5	V
UVLO	VIN Undervoltage lockout	VIN = increasing				4.0	4.5	V
		VIN = decreasing			3.5	3.85		
$V_{OUT(adj)}$	Output voltage adjust range	Over I_{OUT} range			1.2		5.5	V
V_{OUT}	Set-point voltage tolerance	T_A = 25°C, I_{OUT} = 0A					±1.0% (2)	
	Temperature variation	-40°C ≤ T_A ≤ +85°C, I_{OUT} = 0A				±0.3%		
	Line regulation	Over PVIN range, T_A = 25°C, I_{OUT} = 0A				±0.1%		
	Load regulation	Over I_{OUT} range, T_A = 25°C				±0.1%		
	Total output voltage variation	Includes set-point, line, load, and temperature variation					±1.5% (2)	
η	Efficiency	PVIN = VIN = 12 V, I_O = 3 A		V_{OUT} = 5V, f_{SW} = 780kHz		93 %		
				V_{OUT} = 3.3V, f_{SW} = 630kHz		90 %		
				V_{OUT} = 2.5V, f_{SW} = 530kHz		89 %		
				V_{OUT} = 1.8V, f_{SW} = 480kHz		87 %		
				V_{OUT} = 1.5V, f_{SW} = 480kHz		85 %		
				V_{OUT} = 1.2V, f_{SW} = 480kHz		83 %		
		PVIN = VIN = 5 V, I_O = 3 A		V_{OUT} = 3.3V, f_{SW} = 630kHz		94 %		
				V_{OUT} = 2.5V, f_{SW} = 530kHz		92 %		
				V_{OUT} = 1.8V, f_{SW} = 480kHz		90 %		
				V_{OUT} = 1.5V, f_{SW} = 480kHz		88 %		
				V_{OUT} = 1.2V, f_{SW} = 480kHz		86 %		
	Output voltage ripple	20 MHz bandwith				30		mV_{PP}
I_{LIM}	Overcurrent threshold					11		A
	Transient response	1.0 A/µs load step from 50 to 100% $I_{OUT(max)}$		Recovery time		80		µs
				V_{OUT} over/undershoot		60		mV
V_{INH-H}	Inhibit Control	Inhibit High Voltage			1.30		Open (3)	V
V_{INH-L}		Inhibit Low Voltage			–0.3		1.05	
	INH Input current	INH < 1.1 V				-1.15		µA
	INH Hysteresis current	INH > 1.26 V				-3.4		µA
$I_{I(stby)}$	Input standby current	INH pin to AGND				2	4	µA
Power Good	PWRGD Thresholds	V_{OUT} rising		Good		94%		
				Fault		109%		
		V_{OUT} falling		Fault		91%		
				Good		106%		
	PWRGD Low Voltage	I(PWRGD) = 2 mA					0.3	V
f_{SW}	Switching frequency	Over VIN and I_{OUT} ranges, RT/CLK pin OPEN			400	480	560	kHz

(1) The minimum PVIN voltage is 1.7V or (V_{OUT}+ 0.5V) , whichever is greater. VIN must be greater than 4.5 V.
(2) The stated limit of the set-point voltage tolerance includes the tolerance of both the internal voltage reference and the internal adjustment resistor. The overall output voltage tolerance will be affected by the tolerance of the external R_{SET} resistor.
(3) This control pin has an internal pullup. If this pin is left open circuit, the device operates when input power is applied. A small low-leakage (<300 nA) MOSFET is recommended for control. See the application section for further guidance.

Electrical Characteristics (接下页)

over -40°C to 85°C free-air temperature, PVIN = VIN = 12 V, V_{OUT} = 1.8 V, I_{OUT} = 6A,
C_{IN1} = 2 × 22-µF ceramic, C_{IN2} = 68 µF poly-tantalum, C_{OUT1} = 4 × 47-µF ceramic (unless otherwise noted)

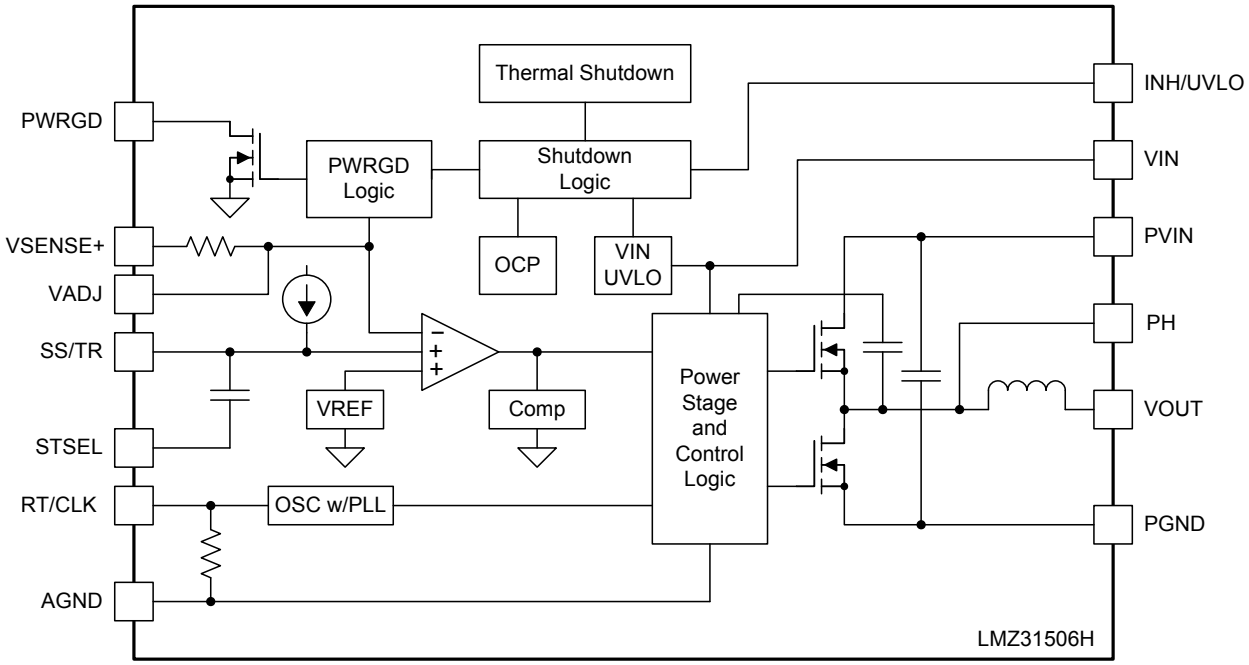
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{CLK}	Synchronization frequency	CLK Control	480		780	kHz
V_{CLK-H}	CLK High-Level Threshold		2.0		5.5	V
V_{CLK-L}	CLK Low-Level Threshold				0.8	V
D_{CLK}	CLK Duty cycle		20%		80%	
	Thermal Shutdown	Thermal shutdown	160	175		°C
		Thermal shutdown hysteresis		10		°C
C_{IN}	External input capacitance	Ceramic	44 (4)			µF
		Non-ceramic	68 (4)			
C_{OUT}	External output capacitance	Ceramic	47 (5)	200	1500	µF
		Non-ceramic		220 (5)	5000	
		Equivalent series resistance (ESR)			35	mΩ

(4) A minimum of 100µF of polymer tantalum and/or ceramic external capacitance is required across the input (VIN and PVIN connected) for proper operation. Locate the capacitor close to the device. See 表 5 for more details. When operating with split VIN and PVIN rails, place 4.7µF of ceramic capacitance directly at the VIN pin.

(5) The amount of required output capacitance varies depending on the output voltage (see 表 3). The amount of required capacitance must include at least 1x 47µF ceramic capacitor. Locate the capacitance close to the device. Adding additional capacitance close to the load improves the response of the regulator to load transients. See 表 3 and 表 5 more details.

4 Device Information

Functional Block Diagram



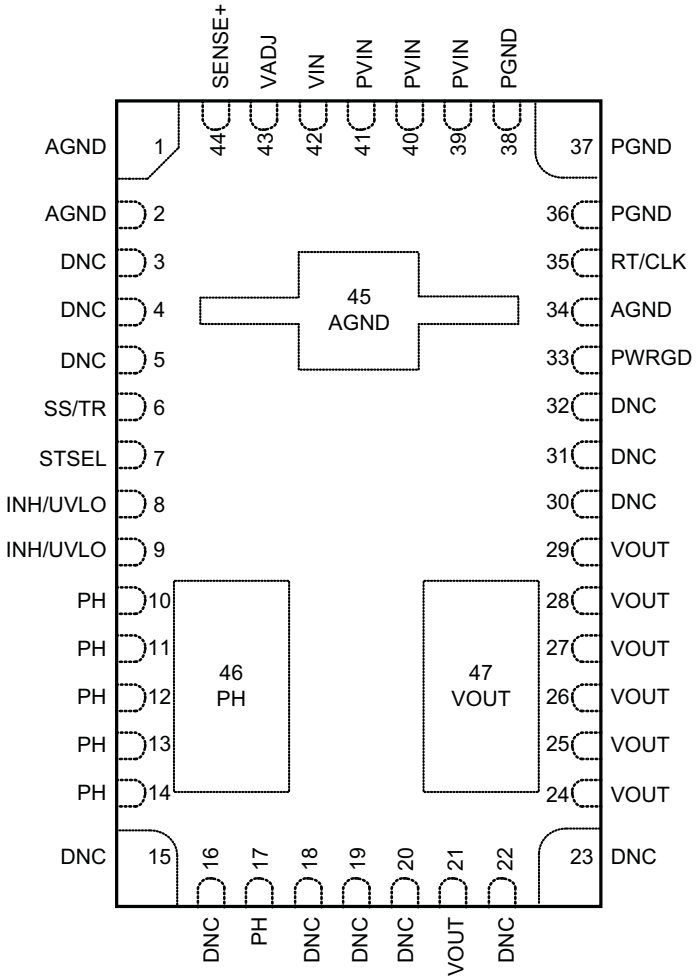
Pin Functions

TERMINAL		DESCRIPTION
NAME	NO.	
AGND	1	Zero VDC reference for the analog control circuitry. Connect AGND to PGND at a single point. Connect near the output capacitors.
	2	
	34	
	45	
INH/UVLO	8	Inhibit and UVLO adjust pin. Use an open drain or open collector output logic to control the INH function. A resistor divider between this pin, AGND and VIN adjusts the UVLO voltage. Tie both pins together when using this control.
	9	
DNC	3	Do not connect. These pins must remain isolated from one another. Do not connect these pins to AGND or to any voltage. These pins must be soldered to isolated pads.
	4	
	5	
	15	
	16	
	18	
	19	
	20	
	22	
	23	
	30	
	31	
	32	
PGND	36	Common ground connection for the PVIN, VIN, and VOUT power connections.
	37	
	38	
PH	10	Phase switch node. These pins should be connected by a small copper island under the device for thermal relief. Do not place any external component on this pin or tie it to a pin of another function.
	11	
	12	
	13	
	14	
	17	
	46	
PWRGD	33	Power good fault pin. Asserts low if the output voltage is low. A pull-up resistor is required.
PVIN	39	Input switching voltage. this pin supplies voltage the power switches of the converter.
	40	
	41	
RT/CLK	35	This pin automatically selects between RT mode and CLK mode. An external timing resistor adjusts the switching frequency of the device. In CLK mode, the device synchronizes to an external clock.
SENSE+	44	Remote sense connection. Connect this pin to VOUT at the load for improved regulation. This pin must be connected to VOUT at the load, or at the device pins.
SS/TR	6	Slow-start and tracking pin. Connecting an external capacitor to this pin adjusts the output voltage rise time. A voltage applied to this pin allows for tracking and sequencing control.
STSEL	7	Slow-start or track feature select. Connect this pin to AGND to enable the internal SS capacitor with a SS interval of approximately 1.1 ms. Leave this pin open to enable the TR feature.
VADJ	43	Connecting a resistor between this pin and AGND sets the output voltage.
VIN	42	Input bias voltage pin. Supplies the control circuitry of the power converter.

Pin Functions (接下页)

TERMINAL		DESCRIPTION
NAME	NO.	
VOUT	21	Output voltage. Connect output capacitors between these pins and PGND.
	24	
	25	
	26	
	27	
	28	
	29	
	47	

RUQ PACKAGE
47 PIN
TOP VIEW



5 Typical Characteristics (PVIN = VIN = 12 V)

The electrical characteristic data has been developed from actual products tested at 25°C. This data is considered typical for the converter. Applies to 图 1, 图 2, and 图 3. The temperature derating curves represent the conditions at which internal components are at or below the manufacturer's maximum operating temperatures. Derating limits apply to devices soldered directly to a 100 mm × 100 mm double-sided PCB with 1 oz. copper. Applies to 图 4.

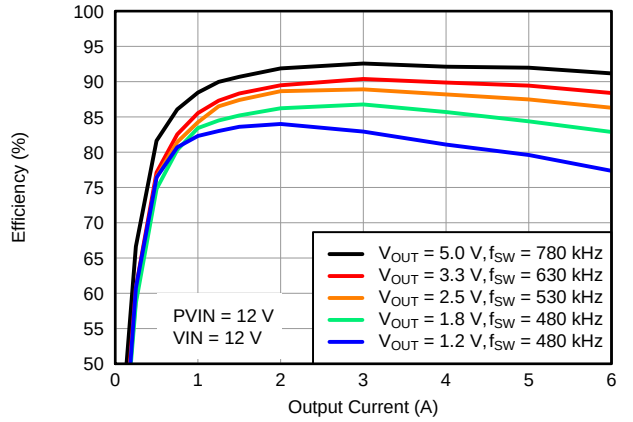


图 1. Efficiency vs. Output Current

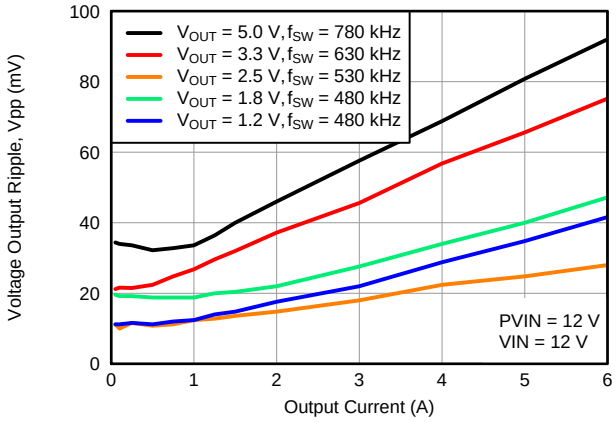


图 2. Voltage Ripple vs. Output Current

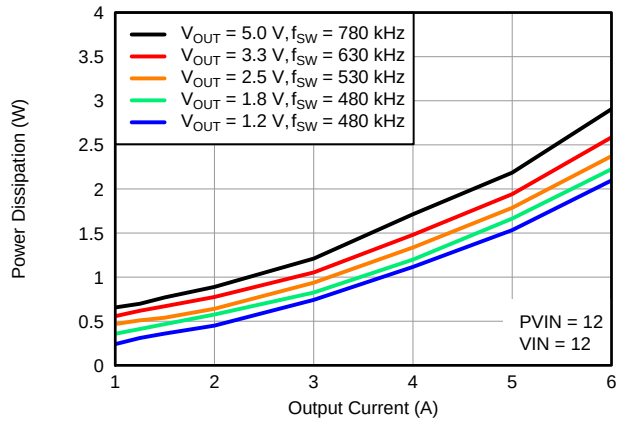


图 3. Power Dissipation vs. Output Current

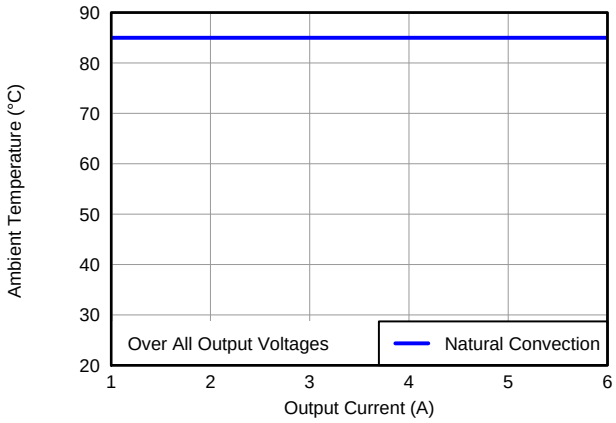


图 4. Safe Operating Area

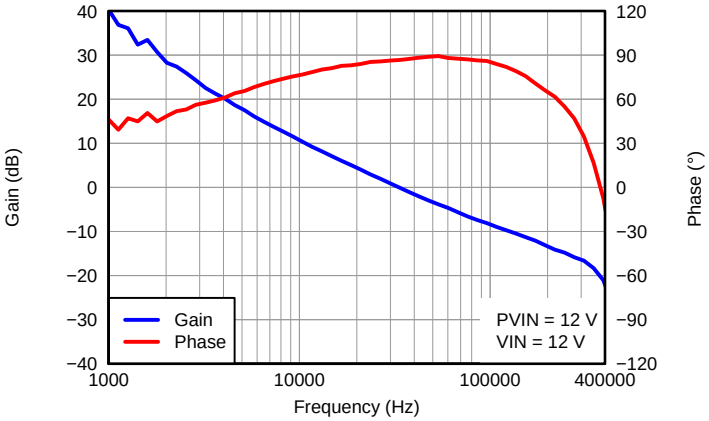


图 5. V_{OUT}=1.2 V, I_{OUT}=3 A, C_{OUT1}=47 µF ceramic, C_{OUT2}= 330 µF POSCAP, f_{SW}=480 kHz

6 Typical Characteristics (PVIN = VIN = 5 V)

The electrical characteristic data has been developed from actual products tested at 25°C. This data is considered typical for the converter. Applies to 图 6, 图 7, and 图 8. The temperature derating curves represent the conditions at which internal components are at or below the manufacturer's maximum operating temperatures. Derating limits apply to devices soldered directly to a 100 mm × 100 mm double-sided PCB with 1 oz. copper. Applies to 图 9.

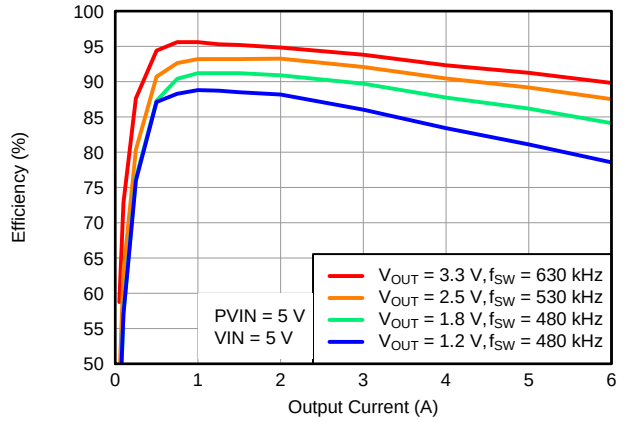


图 6. Efficiency vs. Output Current

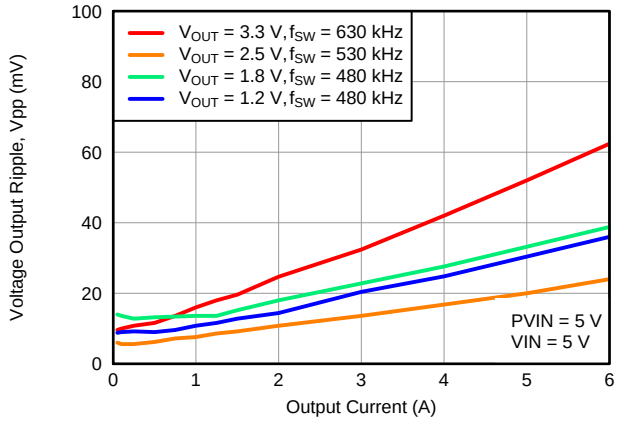


图 7. Voltage Ripple vs. Output Current

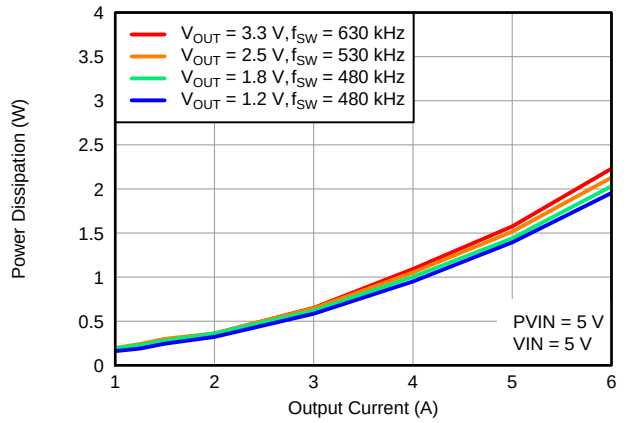


图 8. Power Dissipation vs. Output Current

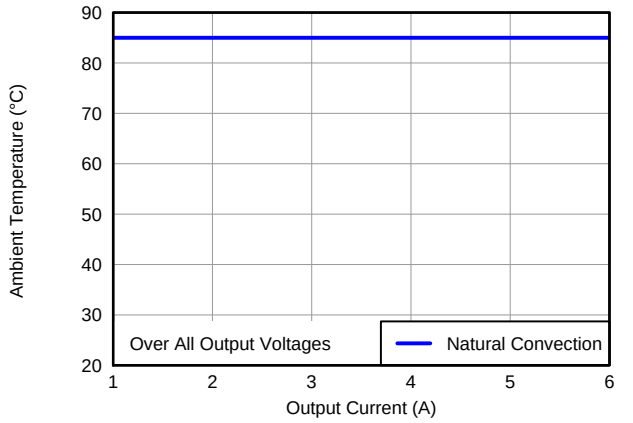


图 9. Safe Operating Area

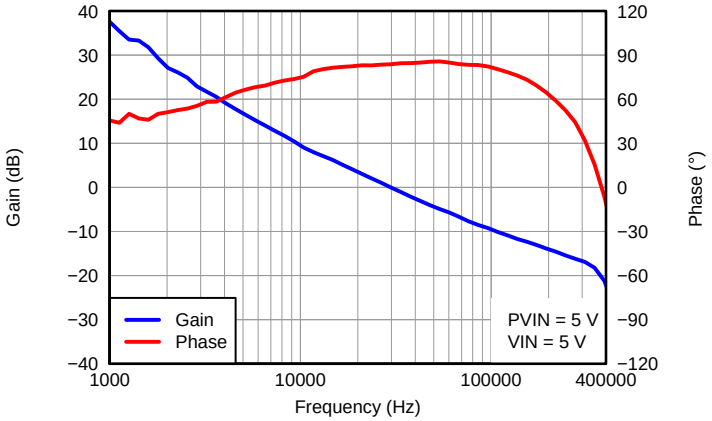


图 10. V_{OUT}=1.2 V, I_{OUT}=3 A, C_{OUT1}=47 µF ceramic, C_{OUT2}= 330 µF POSCAP, f_{SW}=480 kHz

7 Typical Characteristics (PVIN = 12 V, VIN = 5 V)

The electrical characteristic data has been developed from actual products tested at 25°C. This data is considered typical for the converter. Applies to 图 11, 图 12, and 图 13. The temperature derating curves represent the conditions at which internal components are at or below the manufacturer's maximum operating temperatures. Derating limits apply to devices soldered directly to a 100 mm × 100 mm double-sided PCB with 1 oz. copper. Applies to 图 14 and 图 15.

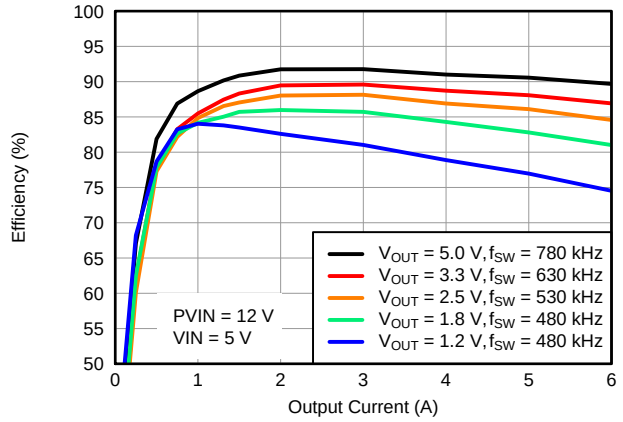


图 11. Efficiency vs. Output Current

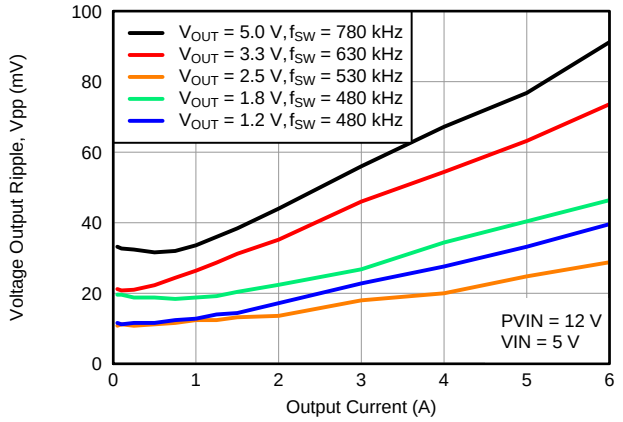


图 12. Voltage Ripple vs. Output Current

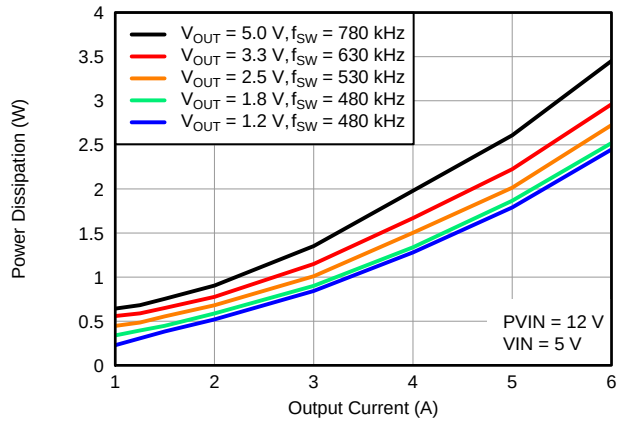


图 13. Power Dissipation vs. Output Current

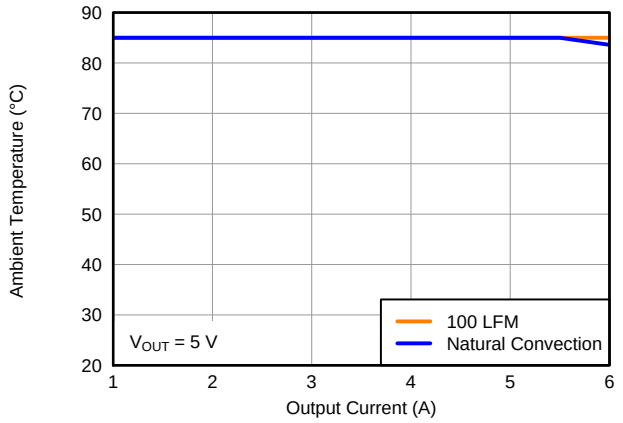


图 14. Safe Operating Area

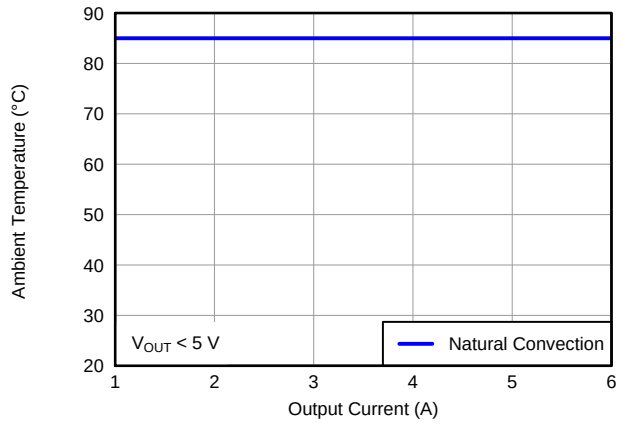


图 15. Safe Operating Area

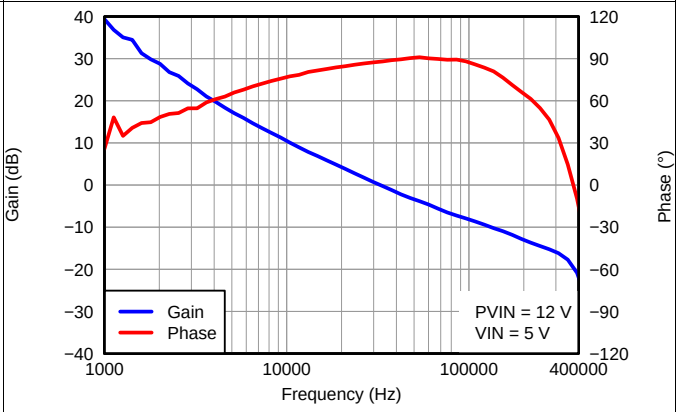


图 16. V_{OUT}=1.2 V, I_{OUT}=3 A, C_{OUT1}=47 µF ceramic, C_{OUT2}= 330 µF POSCAP, f_{SW}=480 kHz

8 Application Information

8.1 Adjusting the Output Voltage

The VADJ control sets the output voltage of the LMZ31506H. The output voltage adjustment range is from 1.2V to 5.5V. The adjustment method requires the addition of R_{SET}, which sets the output voltage, the connection of SENSE+ to VOUT, and in some cases R_{RT} which sets the switching frequency. The R_{SET} resistor must be connected directly between the VADJ (pin 43) and AGND (pin 45). The SENSE+ pin (pin 44) must be connected to VOUT either at the load for improved regulation or at VOUT of the device. The R_{RT} resistor must be connected directly between the RT/CLK (pin 35) and AGND (pin 34).

表 1 gives the standard external R_{SET} resistor for a number of common bus voltages, along with the required R_{RT} resistor for that output voltage.

表 1. Standard R_{SET} Resistor Values for Common Output Voltages

RESISTORS	OUTPUT VOLTAGE V_{OUT} (V)					
	1.2	1.5	1.8	2.5	3.3	5.0
R_{SET} (kΩ)	2.87	1.62	1.13	0.665	0.453	0.267
R_{RT} (kΩ)	open	open	open	1000	332	165

For other output voltages, the value of the required resistor can either be calculated using the following formula, or simply selected from the range of values given in 表 2.

$$R_{SET} = \frac{1.43}{\left(\left(\frac{V_{OUT}}{0.8}\right) - 1\right)} \ (k\Omega) \quad (1)$$

表 2. Standard R_{SET} Resistor Values

V_{OUT} (V)	R_{SET} (kΩ)	R_{RT}(kΩ)	f_{SW}(kHz)	V_{OUT} (V)	R_{SET} (kΩ)	R_{RT}(kΩ)	f_{SW}(kHz)
1.2	2.87	open	480	3.4	0.442	332	630
1.3	2.26	open	480	3.5	0.422	332	630
1.4	1.91	open	480	3.6	0.402	332	630
1.5	1.62	open	480	3.7	0.392	332	630
1.6	1.43	open	480	3.8	0.374	249	680
1.7	1.27	open	480	3.9	0.365	249	680
1.8	1.13	open	480	4.0	0.357	249	680
1.9	1.02	open	480	4.1	0.348	249	680
2.0	0.953	open	480	4.2	0.332	196	730
2.1	0.866	open	480	4.3	0.324	196	730
2.2	0.806	open	480	4.4	0.316	196	730
2.3	0.750	open	480	4.5	0.309	196	730
2.4	0.715	open	480	4.6	0.301	196	730
2.5	0.665	1000	530	4.7	0.294	196	730
2.6	0.634	1000	530	4.8	0.287	165	780
2.7	0.604	1000	530	4.9	0.280	165	780
2.8	0.562	1000	530	5.0	0.267	165	780
2.9	0.536	1000	530	5.1	0.267	165	780
3.0	0.511	499	580	5.2	0.261	165	780
3.1	0.499	499	580	5.3	0.255	165	780
3.2	0.475	499	580	5.4	0.249	165	780
3.3	0.453	332	630	5.5	0.243	165	780

8.2 Capacitor Recommendations for the LMZ31506H Power Supply

8.2.1 Capacitor Technologies

8.2.1.1 Electrolytic, Polymer-Electrolytic Capacitors

When using electrolytic capacitors, high-quality, computer-grade electrolytic capacitors are recommended. Polymer-electrolytic type capacitors are recommended for applications where the ambient operating temperature is less than 0°C. The Sanyo OS-CON capacitor series is suggested due to the lower ESR, higher rated surge, power dissipation, ripple current capability, and small package size. Aluminum electrolytic capacitors provide adequate decoupling over the frequency range of 2 kHz to 150 kHz, and are suitable when ambient temperatures are above 0°C.

8.2.1.2 Ceramic Capacitors

The performance of aluminum electrolytic capacitors is less effective than ceramic capacitors above 150 kHz. Multilayer ceramic capacitors have a low ESR and a resonant frequency higher than the bandwidth of the regulator. They can be used to reduce the reflected ripple current at the input as well as improve the transient response of the output.

8.2.1.3 Tantalum, Polymer-Tantalum Capacitors

Polymer-tantalum type capacitors are recommended for applications where the ambient operating temperature is less than 0°C. The Sanyo POSCAP series and Kemet T530 capacitor series are recommended rather than many other tantalum types due to their lower ESR, higher rated surge, power dissipation, ripple current capability, and small package size. Tantalum capacitors that have no stated ESR or surge current rating are not recommended for power applications.

8.2.2 Input Capacitor

The LMZ31506H requires a minimum input capacitance of 100 µF of ceramic and/or polymer-tantalum capacitors. The ripple current rating of the capacitor must be at least 450 mArms. 表 5 includes a preferred list of capacitors by vendor.

8.2.3 Output Capacitor

The required output capacitance is determined by the output voltage of the LMZ31506H. See 表 3 for the amount of required capacitance. The required output capacitance can be comprised of either all ceramic capacitors, or a combination of ceramic and bulk capacitors. The required output capacitance must include at least 1x 47 µF ceramic capacitor. When adding additional non-ceramic bulk capacitors, low-ESR devices like the ones recommended in 表 5 are required. The required capacitance above the minimum is determined by actual transient deviation requirements. See 表 4 for typical transient response values for several output voltage, input voltage and capacitance combinations. 表 5 includes a preferred list of capacitors by vendor.

表 3. Required Output Capacitance

V_{OUT} RANGE (V)		MINIMUM REQUIRED C_{OUT} (µF)
MIN	MAX	
1.2	< 3.0	200(1)
3.0	< 4.0	100(1)
4.0	5.5	47 µF ceramic

(1) Minimum required must include at least one 47 µF ceramic capacitor.

表 4. Output Voltage Transient Response

C_{IN1} = 2 x 22 µF CERAMIC, C_{IN2} = 68 µF POSCAP, LOAD STEP = 3 A, 1 A/µs						
V_{OUT} (V)	PV_{IN} (V)	C_{OUT1} Ceramic	C_{OUT2} BULK	VOLTAGE DEVIATION (mV)	PEAK-PEAK (mV)	RECOVERY TIME (µs)
1.2	3.3	4x 47 µF	None	73	137	70
		1x 47 µF	330 µF	50	90	75
	5	4x 47 µF	None	63	117	70
		1x 47 µF	330 µF	45	85	75
	12	4x 47 µF	None	45	109	70
		1x 47 µF	330 µF	35	70	75
1.5	3.3	4x 47 µF	None	80	160	80
		1x 47 µF	220 µF	65	130	70
	5	4x 47 µF	None	60	115	80
		1x 47 µF	220 µF	60	120	70
	12	4x 47 µF	None	45	98	80
		1x 47 µF	220 µF	50	100	70
1.8	3.3	4x 47 µF	None	90	180	80
		1x 47 µF	220 µF	72	142	110
	5	4x 47 µF	None	80	160	80
		1x 47 µF	220 µF	67	132	110
	12	4x 47 µF	None	60	120	80
		1x 47 µF	220 µF	60	119	110
2.5	3.3	4x 47 µF	None	108	214	75
		1x 47 µF	100 µF	93	186	110
	5	4x 47 µF	None	100	200	75
		1x 47 µF	100 µF	92	180	110
	12	4x 47 µF	None	88	174	75
		1x 47 µF	100 µF	80	157	110
3.3	5	2x 47 µF	None	160	320	100
		1x 47 µF	100 µF	110	220	100
	12	2x 47 µF	None	140	280	100
		1x 47 µF	100 µF	100	200	100
5.0	5	1x 47 µF	None	200	400	100
		1x 47 µF	100 µF	150	300	130
	12	1x 47 µF	None	180	360	100
		1x 47 µF	100 µF	150	300	130

表 5. Recommended Input/Output Capacitors (1)

VENDOR	SERIES	PART NUMBER	CAPACITOR CHARACTERISTICS		
			WORKING VOLTAGE (V)	CAPACITANCE (µF)	ESR (2) (mΩ)
Murata	X5R	GRM32ER61E226K	16	22	2
TDK	X5R	C3225X5R0J476K	6.3	47	2
Murata	X5R	GRM32ER60J476M	6.3	47	2
Sanyo	POSCAP	16TQC68M	16	68	50
Kemet	T520	T520V107M010ASE025	10	100	25
Sanyo	POSCAP	6TPE100MI	6.3	100	25
Sanyo	POSCAP	2R5TPE220M7	2.5	220	7
Kemet	T530	T530D227M006ATE006	6.3	220	6
Kemet	T530	T530D337M006ATE010	6.3	330	10
Sanyo	POSCAP	2TPF330M6	2.0	330	6
Sanyo	POSCAP	6TPE330MFL	6.3	330	15

(1) **Capacitor Supplier Verification**
Please verify availability of capacitors identified in this table.
RoHS, Lead-free and Material Details
Please consult capacitor suppliers regarding material composition, RoHS status, lead-free status, and manufacturing process requirements.
(2) Maximum ESR @ 100kHz, 25°C.

8.3 Transient Response

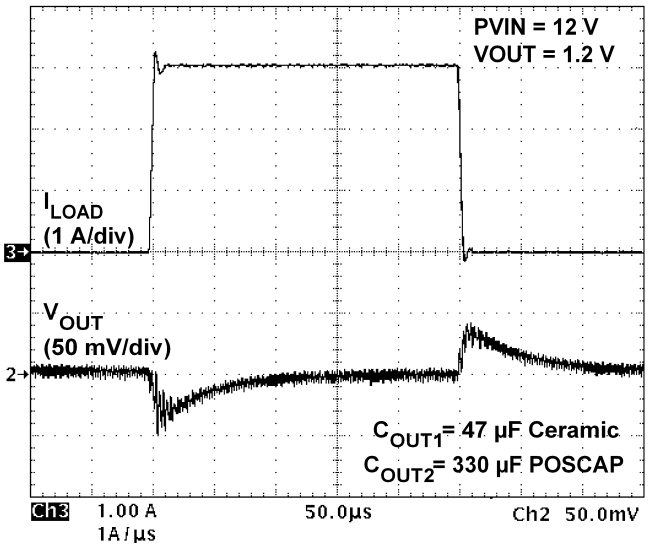


图 17. PVIN = 12V, VOUT = 1.2V, 3A Load Step

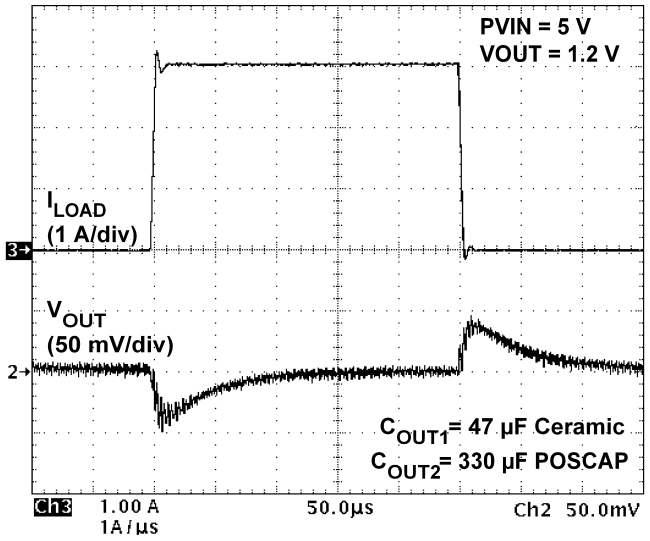


图 18. PVIN = 5V, VOUT = 1.2V, 3A Load Step

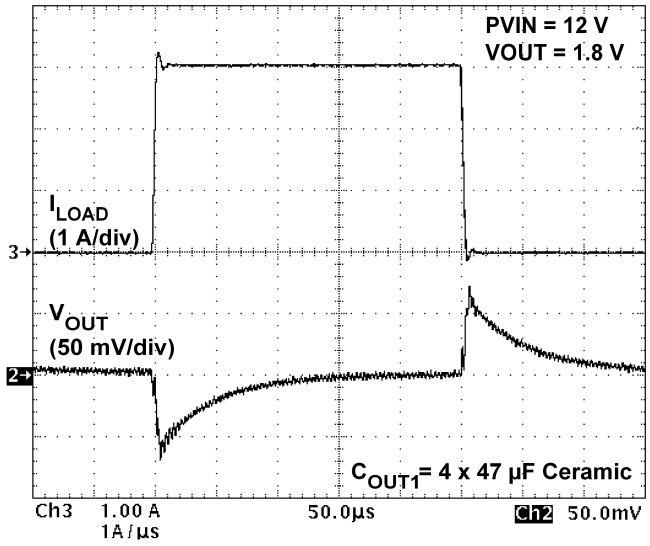


图 19. PVIN = 12V, VOUT = 1.8V, 3A Load Step

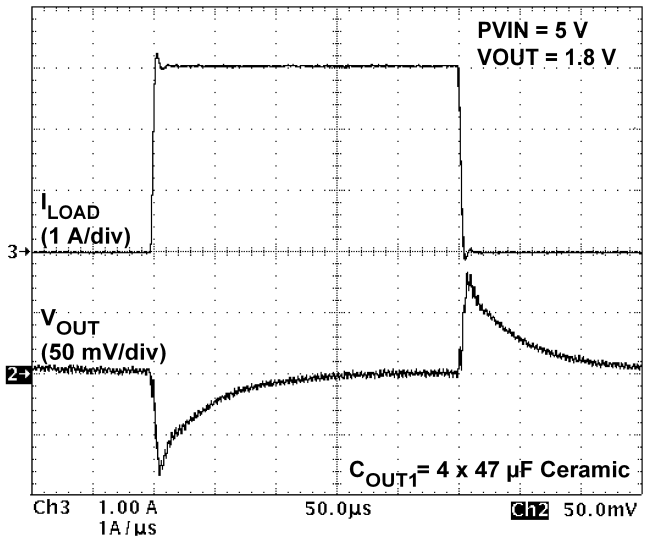


图 20. PVIN = 5V, VOUT = 1.8V, 3A Load Step

Transient Response (接下页)

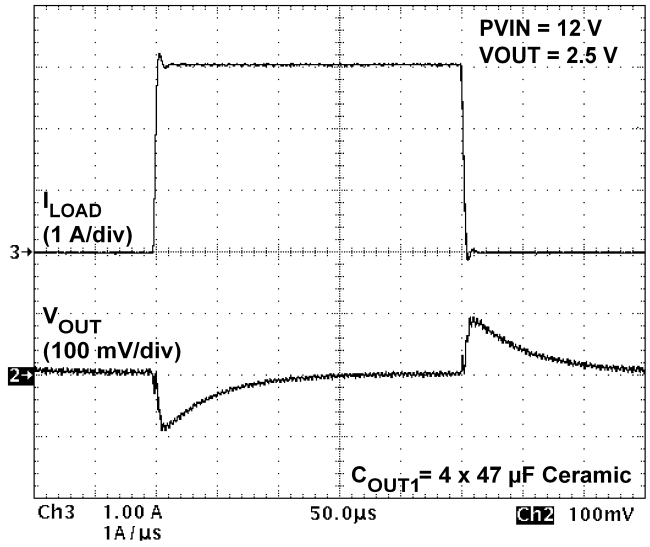


图 21. PVIN = 12V, VOUT = 2.5V, 3A Load Step

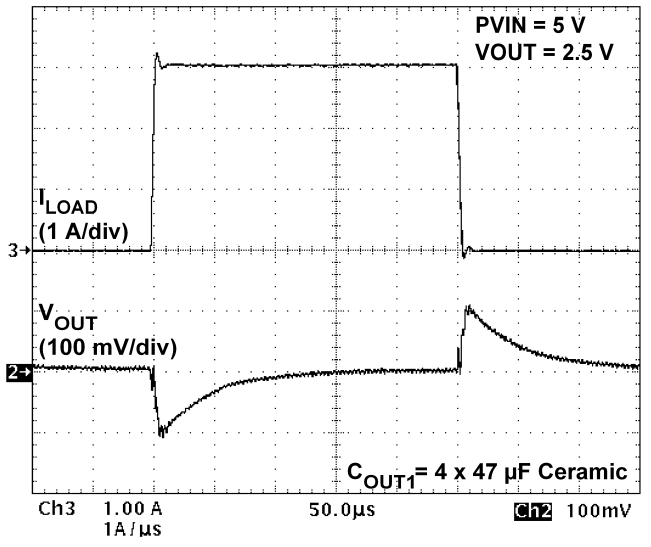


图 22. PVIN = 5V, VOUT = 2.5V, 3A Load Step

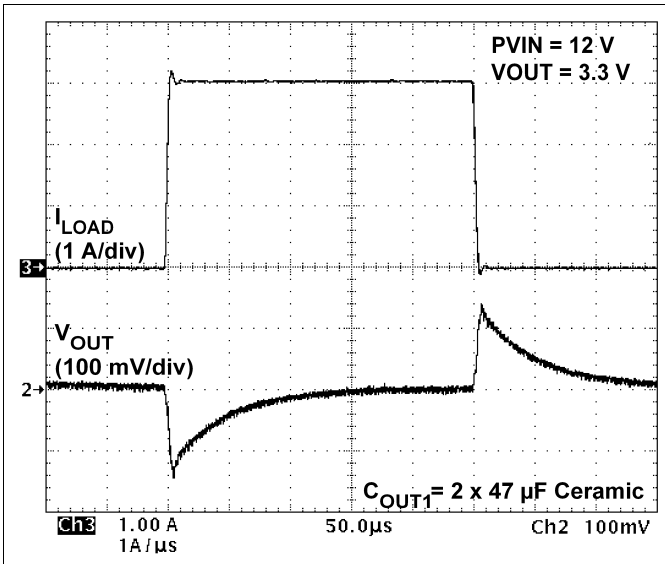


图 23. PVIN = 12V, VOUT = 3.3V, 3A Load Step

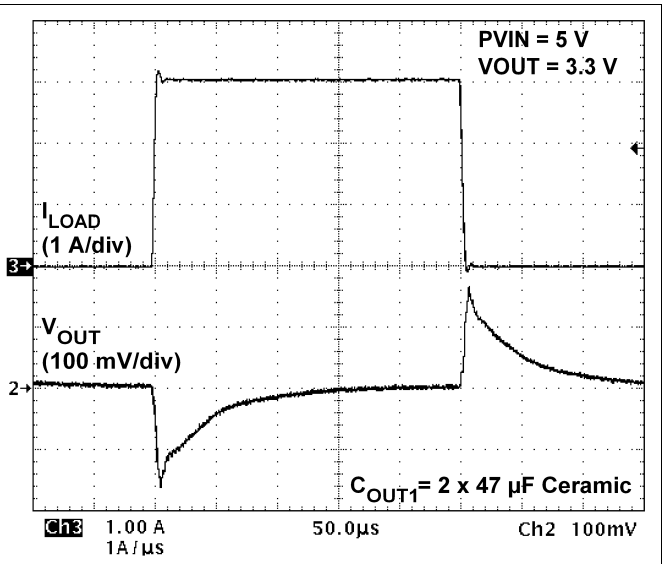


图 24. PVIN = 5V, VOUT = 3.3V, 3A Load Step

8.4 Application Schematics

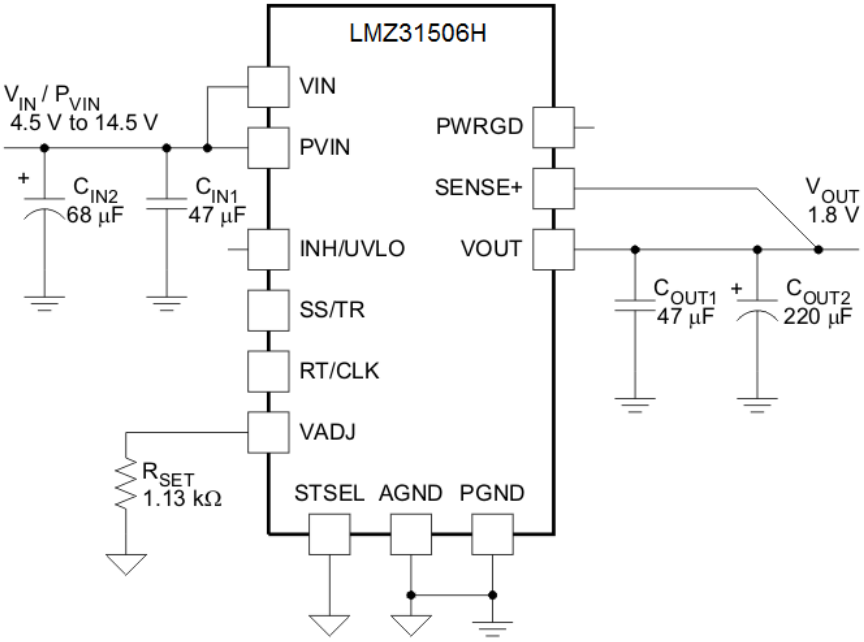


图 25. Typical Schematic
PVIN = VIN = 4.5 V to 14.5 V, VOUT = 1.8 V

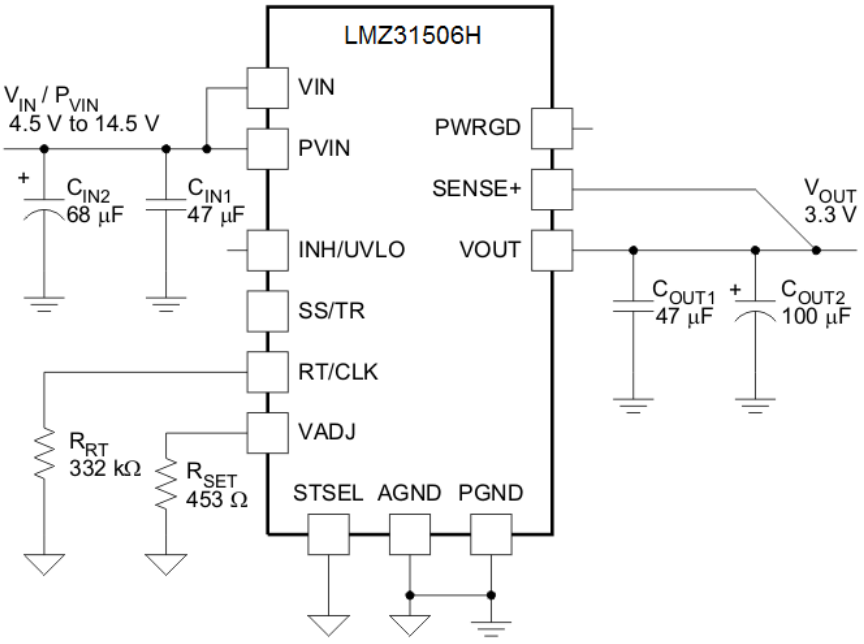


图 26. Typical Schematic
PVIN = VIN = 4.5 V to 14.5 V, VOUT = 3.3 V

Application Schematics (接下页)

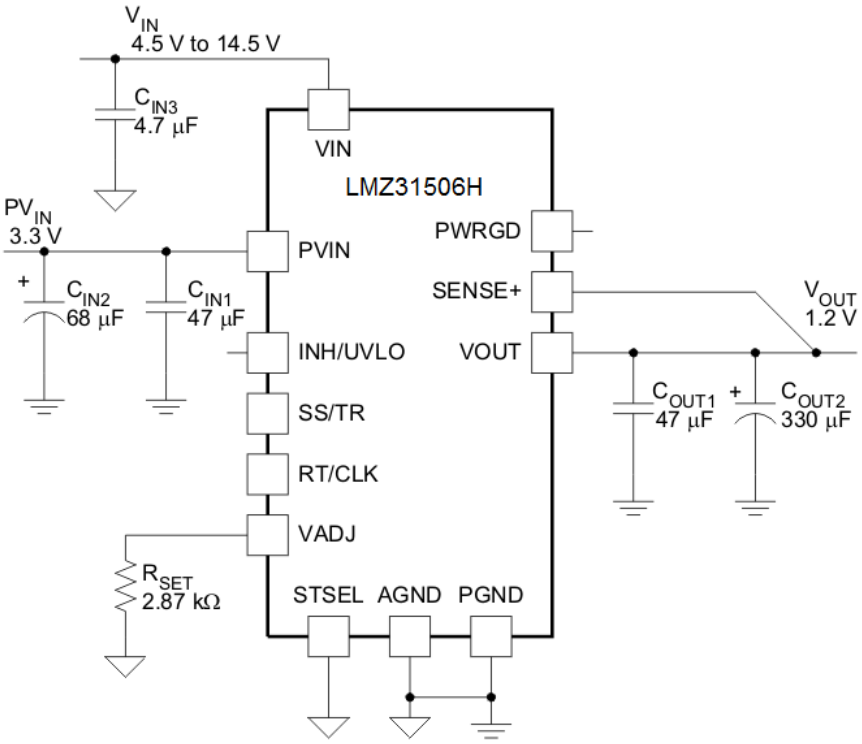


图 27. Typical Schematic
PVIN = 3.3 V, VIN = 4.5 V to 14.5 V, VOUT = 1.2 V

8.5 Custom Design With WEBENCH® Tools

Click here to create a custom design using the LMZ31506H device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

8.6 VIN and PVIN Input Voltage

The LMZ31506H allows for a variety of applications by using the VIN and PVIN pins together or separately. The VIN voltage supplies the internal control circuits of the device. The PVIN voltage provides the input voltage to the power converter system.

If tied together, the input voltage for the VIN pin and the PVIN pin can range from 4.5 V to 14.5 V. If using the VIN pin separately from the PVIN pin, the VIN pin must be between 4.5 V and 14.5 V, and the PVIN pin can range from as low as 1.7 V to 14.5 V. A voltage divider connected to the INH/UVLO pin can adjust the either input voltage UVLO appropriately. See the Programmable Undervoltage Lockout (UVLO) section of this datasheet for more information.

8.7 Power Good (PWRGD)

The PWRGD pin is an open drain output. Once the voltage on the SENSE+ pin is between 94% and 106% of the set voltage, the PWRGD pin pull-down is released and the pin floats. The recommended pull-up resistor value is between 10 kΩ and 100 kΩ to a voltage source that is 5.5 V or less. The PWRGD pin is in a defined state once VIN is greater than 1.0 V, but with reduced current sinking capability. The PWRGD pin achieves full current sinking capability once the VIN pin is above 4.5V. The PWRGD pin is pulled low when the voltage on SENSE+ is lower than 91% or greater than 109% of the nominal set voltage. Also, the PWRGD pin is pulled low if the input UVLO or thermal shutdown is asserted, the INH pin is pulled low, or the SS/TR pin is below 1.4 V.

8.8 Power-Up Characteristics

When configured as shown in the front page schematic, the LMZ31506H produces a regulated output voltage following the application of a valid input voltage. During the power-up, internal soft-start circuitry slows the rate that the output voltage rises, thereby limiting the amount of in-rush current that can be drawn from the input source. The soft-start circuitry introduces a short time delay from the point that a valid input voltage is recognized. 图 28 shows the start-up waveforms for a LMZ31506H, operating from a 5-V input (PVIN=VIN) and with the output voltage adjusted to 1.8 V. 图 29 shows the start-up waveforms for a LMZ31506H starting up into a pre-biased output voltage. The waveforms were measured with a 3-A constant current load.

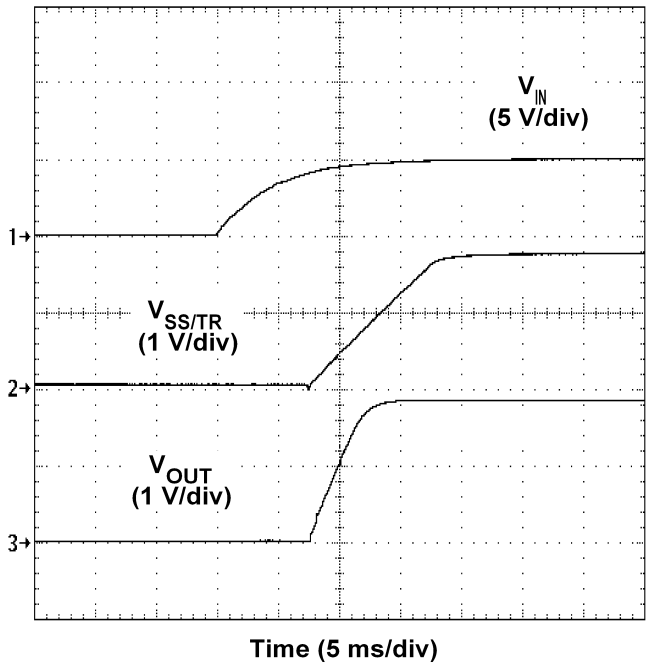


图 28. Start-Up Waveforms

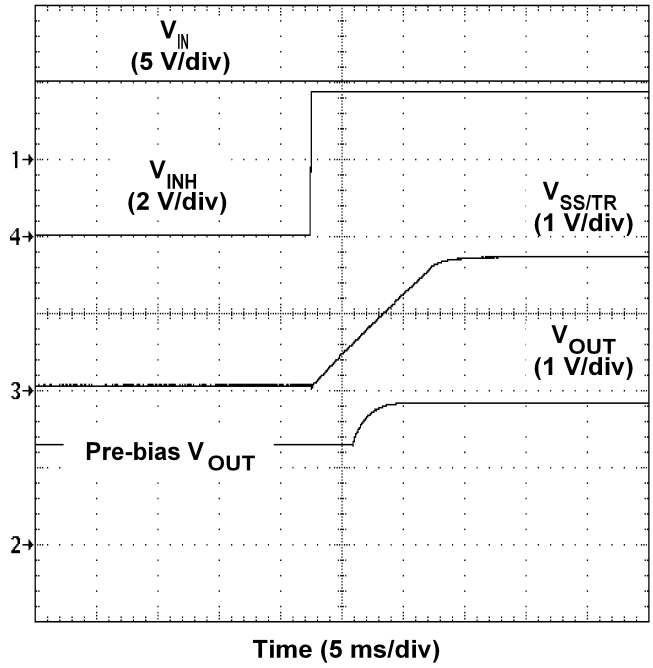


图 29. Start-up into Pre-bias

8.9 Pre-Biased Start-Up

The LMZ31506H has been designed to prevent discharging a pre-biased output. During monotonic pre-biased startup, the LMZ31506H does not allow current to sink until the SS/TR pin voltage is higher than 1.4 V.

8.10 Remote Sense

The SENSE+ pin must be connected to V_{OUT} at the load, or at the device pins.

Connecting the SENSE+ pin to V_{OUT} at the load improves the load regulation performance of the device by allowing it to compensate for any I-R voltage drop between its output pins and the load. An I-R drop is caused by the high output current flowing through the small amount of pin and trace resistance. This should be limited to a maximum of 300 mV.

注

The remote sense feature is not designed to compensate for the forward drop of nonlinear or frequency dependent components that may be placed in series with the converter output. Examples include OR-ing diodes, filter inductors, ferrite beads, and fuses. When these components are enclosed by the SENSE+ connection, they are effectively placed inside the regulation control loop, which can adversely affect the stability of the regulator.

8.11 Output On/Off Inhibit (INH)

The INH pin provides electrical on/off control of the device. Once the INH pin voltage exceeds the threshold voltage, the device starts operation. If the INH pin voltage is pulled below the threshold voltage, the regulator stops switching and enters low quiescent current state.

The INH pin has an internal pull-up current source, allowing the user to float the INH pin for enabling the device. If an application requires controlling the INH pin, use an open drain/collector device, or a suitable logic gate to interface with the pin.

图 30 shows the typical application of the inhibit function. The Inhibit control has its own internal pull-up to VIN potential. An open-collector or open-drain device is recommended to control this input.

Turning Q1 on applies a low voltage to the inhibit control (INH) pin and disables the output of the supply, shown in 图 31. If Q1 is turned off, the supply executes a soft-start power-up sequence, as shown in 图 32. A regulated output voltage is produced within 10 ms. The waveforms were measured with a 3-A constant current load.

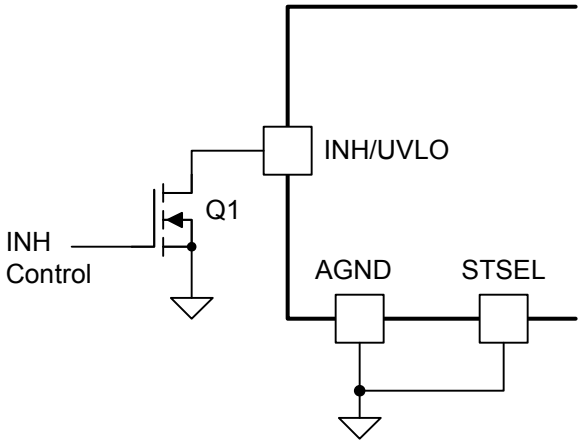


图 30. Typical Inhibit Control

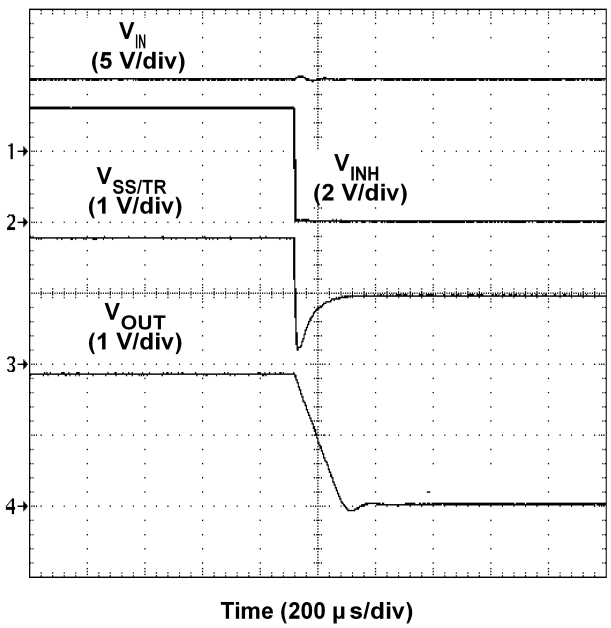


图 31. Inhibit Turn-Off

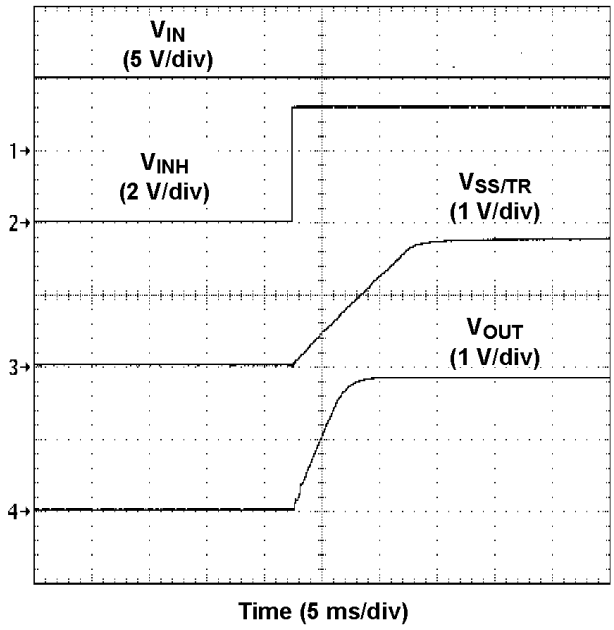


图 32. Inhibit Turn-On

8.12 Slow Start (SS/TR)

Connecting the STSEL pin to AGND and leaving SS/TR pin open enables the internal SS capacitor with a slow start interval of approximately 1.1 ms. Adding additional capacitance between the SS pin and AGND increases the slow start time. 表 6 shows an additional SS capacitor connected to the SS/TR pin and the STSEL pin connected to AGND. See 表 6 below for SS capacitor values and timing interval.

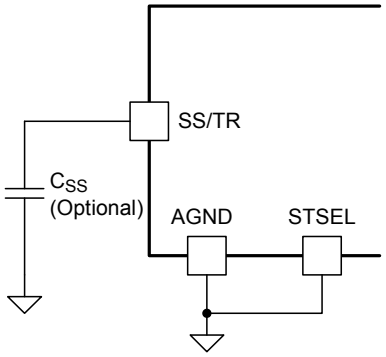


图 33. Slow-Start Capacitor (C_{SS}) and STSEL Connection

表 6. Slow-Start Capacitor Values and Slow-Start Time

C_{SS} (pF)	open	2200	4700	10000	15000	22000	25000
SS Time (msec)	1.1	1.9	2.8	4.6	6.4	8.8	9.8

8.13 Overcurrent Protection

For protection against load faults, the LMZ31506H uses current limiting. The device is protected from overcurrent conditions by cycle-by-cycle current limiting. During an overcurrent condition the output current is limited and the output voltage is reduced, as shown in 图 34. When the overcurrent condition is removed, the output voltage returns to the established voltage, as shown in 图 35.

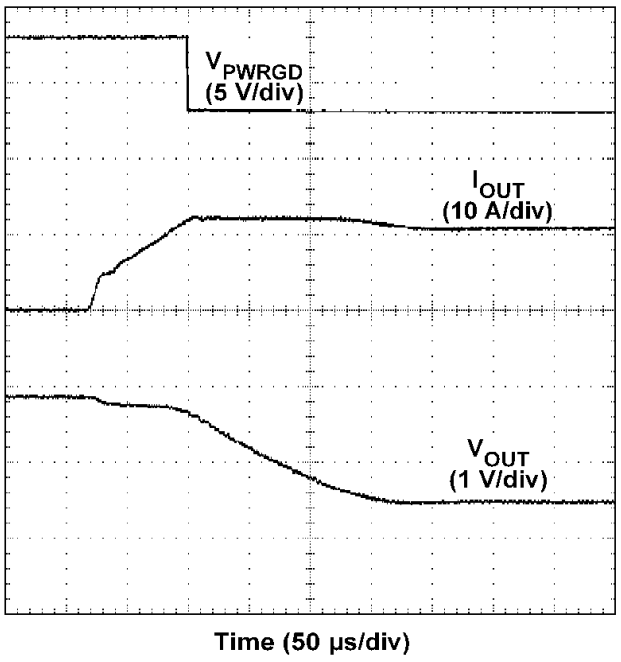


图 34. Overcurrent Limiting

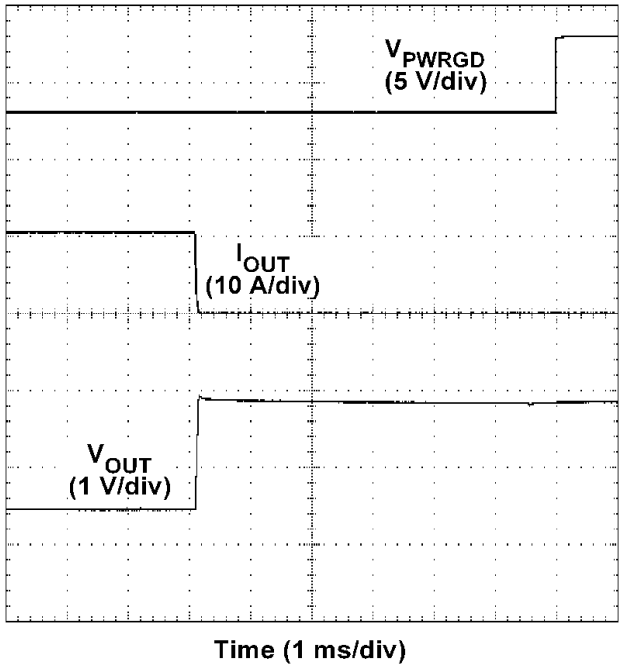


图 35. Removal of Overcurrent Condition

8.14 Synchronization (CLK)

An internal phase locked loop (PLL) has been implemented to allow synchronization between 480 kHz and 780 kHz, and to easily switch from RT mode to CLK mode. To implement the synchronization feature, connect a square wave clock signal to the RT/CLK pin with a duty cycle between 20% to 80%. The clock signal amplitude must transition lower than 0.8 V and higher than 2.0 V. The start of the switching cycle is synchronized to the falling edge of RT/CLK pin. In applications where both RT mode and CLK mode are needed, the device can be configured as shown in .

Before the external clock is present, the device works in RT mode and the switching frequency is set by RT resistor. When the external clock is present, the CLK mode overrides the RT mode. The first time the CLK pin is pulled above the RT/CLK high threshold (2.0 V), the device switches from RT mode to th CLK mode and the RT/CLK pin becomes high impedance as the PLL starts to lock onto the frequency of the external clock. It is not recommended to switch from CLK mode back to RT mode because the internal switching frequency drops to 100 kHz first before returning to the switching frequency set by the RT resistor (R_{RT}).

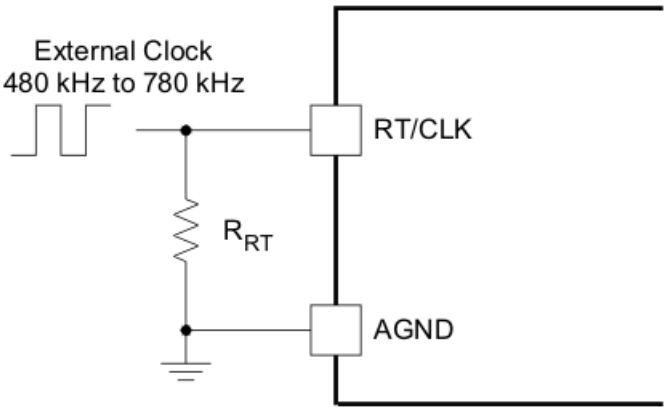


图 36. CLK/RT Configuration

The synchronization frequency must be selected based on the output voltages of the devices being synchronized. 表 7 shows the allowable frequencies for a given range of output voltages. For the most efficient solution, always synchronize to the lowest allowable frequency. For example, an application requires synchronizing three LMZ31506H devices with output voltages of 1.2 V, 1.8 V and 2. 5 V, all powered from PVIN = 12 V. 表 7 shows that all three output voltages can be synchronized to either 530 kHz, 580 kHz, or 630 kHz. For best efficiency, choose 530 kHz as the sychronization frequency.

表 7. Synchronization Frequency vs Output Voltage

SYNCHRONIZATION FREQUENCY (kHz)	R_{RT} (kΩ)	PVIN = 12 V		PVIN = 5 V	
		V_{OUT} RANGE (V)		V_{OUT} RANGE (V)	
		MIN	MAX	MIN	MAX
480	OPEN	1.2	2.5	1.2	4.5
530	1000	1.2	2.9		
580	499	1.2	3.2		
630	332	1.2	3.7		
680	249	1.3	4.1		
730	196	1.4	4.7		
780	165	1.5	5.5		

8.15 Sequencing (SS/TR)

Many of the common power supply sequencing methods can be implemented using the SS/TR, INH and PWRGD pins. The sequential method is illustrated in 图 37 using two LMZ31506H devices. The PWRGD pin of the first device is coupled to the INH pin of the second device which enables the second power supply once the primary supply reaches regulation. 图 38 shows sequential turn-on waveforms of two LMZ31506H devices.

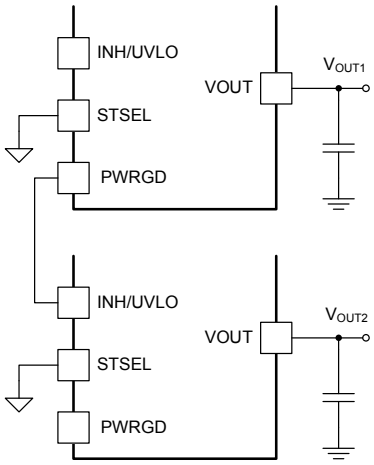


图 37. Sequencing Schematic

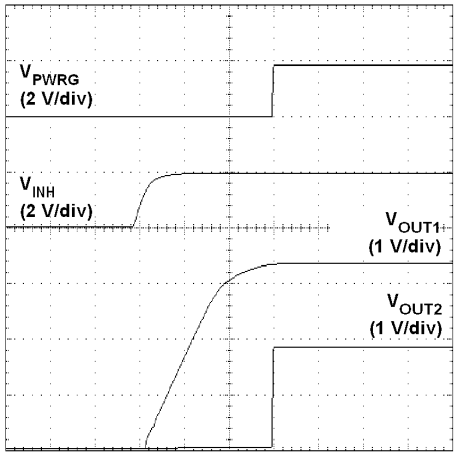


图 38. Sequencing Waveforms

Simultaneous power supply sequencing can be implemented by connecting the resistor network of R1 and R2 shown in 图 39 to the output of the power supply that needs to be tracked or to another voltage reference source. 图 40 shows simultaneous turn-on waveforms of two LMZ31506H devices. Use 公式 2 and 公式 3 to calculate the values of R1 and R2.

$$R1 = \frac{(V_{OUT2} \times 12.6)}{0.8} (k\Omega) \quad (2)$$

$$R2 = \frac{0.8 \times R1}{(V_{OUT2} - 0.8)} (k\Omega) \quad (3)$$

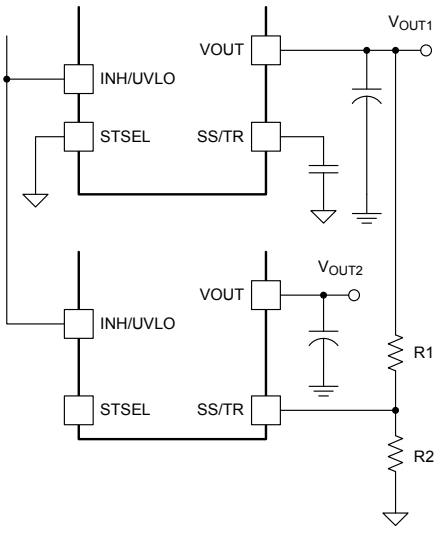


图 39. Simultaneous Tracking Schematic

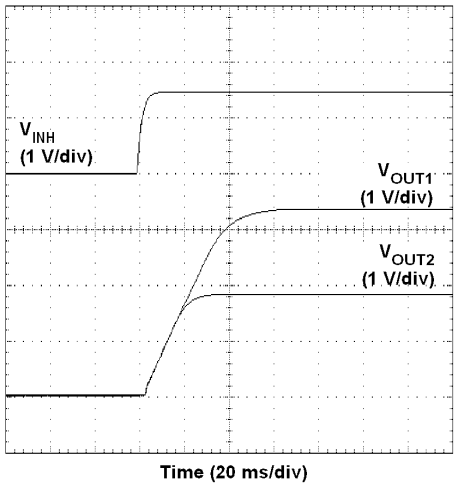


图 40. Simultaneous Tracking Waveforms

8.16 Programmable Undervoltage Lockout (UVLO)

The LMZ31506H implements internal UVLO circuitry on the VIN pin. The device is disabled when the VIN pin voltage falls below the internal VIN UVLO threshold. The internal VIN UVLO rising threshold is 4.5 V(max) with a typical hysteresis of 150 mV.

If an application requires either a higher UVLO threshold on the VIN pin or a higher UVLO threshold for a combined VIN and PVIN, then the UVLO pin can be configured as shown in 图 41 or 图 42. 表 8 lists standard values for R_{UVLO1} and R_{UVLO2} to adjust the VIN UVLO voltage up.

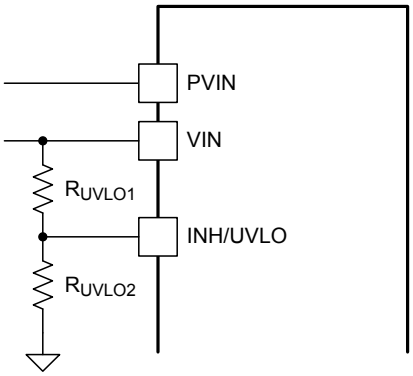


图 41. Adjustable VIN UVLO

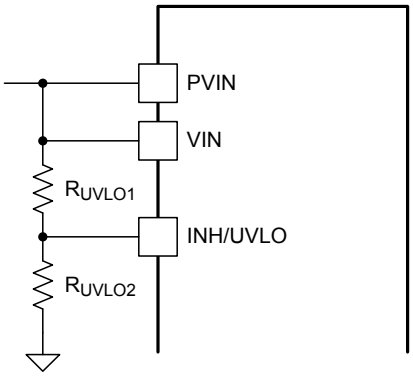


图 42. Adjustable VIN and PVIN Undervoltage Lockout

表 8. Standard Resistor values for Adjusting VIN UVLO

VIN UVLO (V)	5.0	5.5	6.0	6.5	7.0	7.5	8.0	8.5	9.0	9.5	10.0
R_{UVLO1} (kΩ)	68.1	68.1	68.1	68.1	68.1	68.1	68.1	68.1	68.1	68.1	68.1
R_{UVLO2} (kΩ)	21.5	18.7	16.9	15.4	14.0	13.0	12.1	11.3	10.5	9.76	9.31
Hysteresis (V)	400	415	430	450	465	480	500	515	530	550	565

For a split rail application, if a secondary UVLO on PVIN is required, VIN must be ≥ 4.5V. 图 43 shows the PVIN UVLO configuration. Use 表 9 to select R_{UVLO1} and R_{UVLO2} for PVIN. If PVIN UVLO is set for less than 3.0 V, a 5.1-V zener diode should be added to clamp the voltage on the UVLO pin below 6 V.

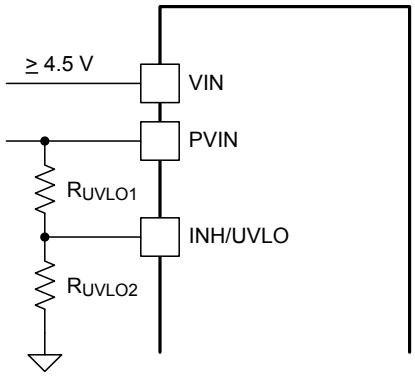


图 43. Adjustable PVIN Undervoltage Lockout, (VIN ≥4.5 V)

表 9. Standard Resistor Values for Adjusting PVIN UVLO, (VIN ≥4.5 V)

PVIN UVLO (V)	2.0	2.5	3.0	3.5	4.0	4.5	
R_{UVLO1} (kΩ)	68.1	68.1	68.1	68.1	68.1	68.1	For higher PVIN UVLO voltages see Table UV for resistor values
R_{UVLO2} (kΩ)	95.3	60.4	44.2	34.8	28.7	24.3	
Hysteresis (V)	300	315	335	350	365	385	

8.17 Thermal Shutdown

The internal thermal shutdown circuitry forces the device to stop switching if the junction temperature exceeds 175°C typically. The device reinitiates the power up sequence when the junction temperature drops below 165°C typically.

8.18 Layout Considerations

To achieve optimal electrical and thermal performance, an optimized PCB layout is required. 图 44 and 图 45 show two layers of a typical PCB layout. Some considerations for an optimized layout are:

- Use large copper areas for power planes (VIN, VOUT, and PGND) to minimize conduction loss and thermal stress.
- Place ceramic input and output capacitors close to the device pins to minimize high frequency noise.
- Locate additional output capacitors between the ceramic capacitor and the load.
- Place a dedicated AGND copper area beneath the LMZ31506H.
- Isolate the PH copper area from the VOUT copper area using the AGND copper area.
- Connect the AGND and PGND copper area at one point as ahown below.
- Place R_{SET}, R_{RT}, and C_{SS} as close as possible to their respective pins.
- Use multiple vias to connect the power planes to internal layers.

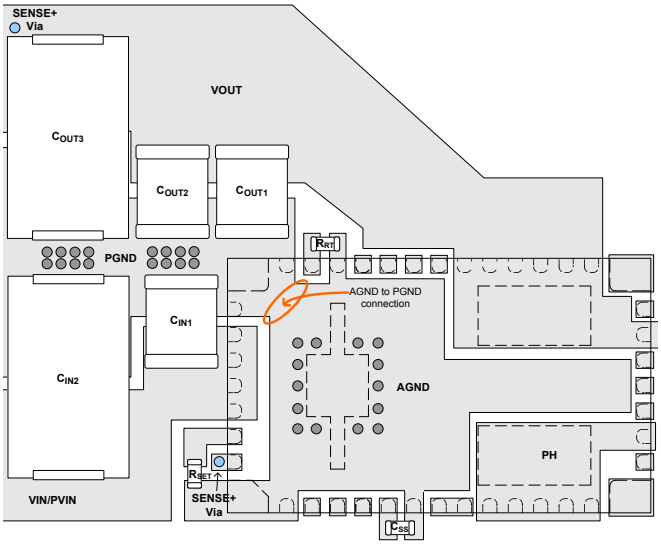


图 44. Typical Top-Layer Recommended Layout

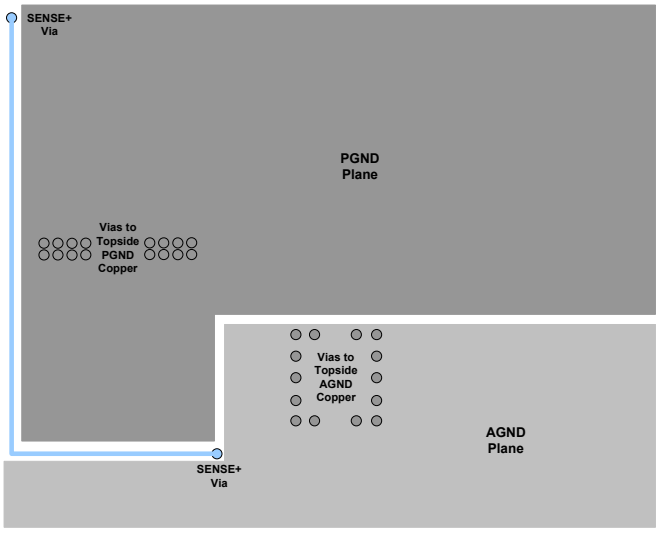


图 45. Typical GND-Layer Recommended Layout

8.19 EMI

The LMZ31506H is compliant with EN55022 Class B radiated emissions. 图 46 and 图 47 show typical examples of radiated emissions plots for the LMZ31506H operating from 5V and 12V respectively. Both graphs include the plots of the antenna in the horizontal and vertical positions.

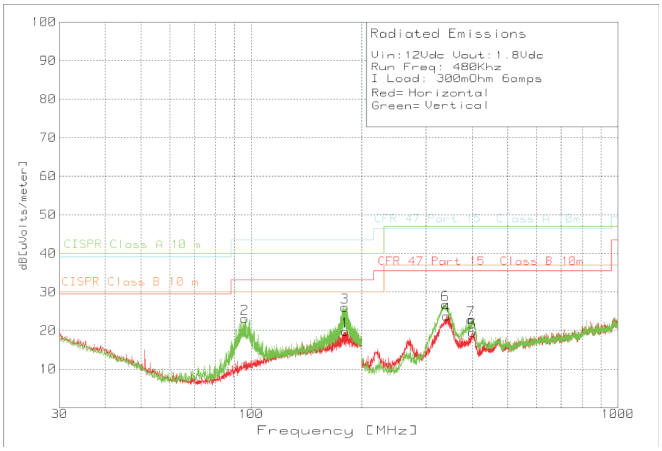


图 46. Radiated Emissions 5-V Input, 1.8-V Output, 6-A Load (EN55022 Class B)

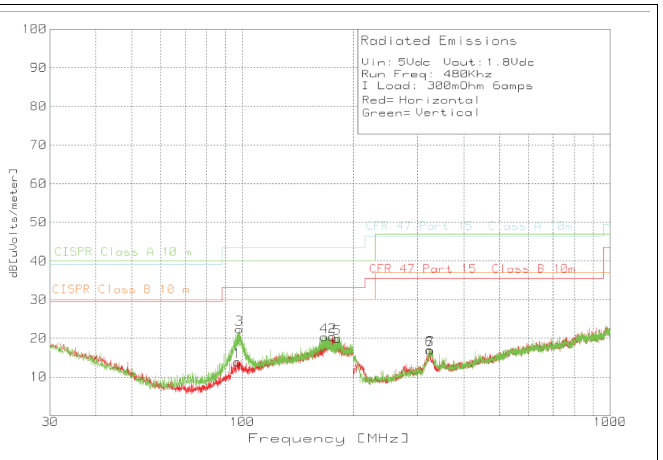


图 47. Radiated Emissions 12-V Input, 1.8-V Output, 6-A Load (EN55022 Class B)

9 Revision History

注：之前版本的页码可能与当前版本有所不同。

Changes from Revision A (June 2017) to Revision B **Page**

- 添加 LMZ31506H 的 WEBENCH® 设计链接 1
- Increased the peak reflow temperature and maximum number of reflows to JEDEC specifications for improved manufacturability 2
- 添加*开发支持* 部分 29
- 添加*机械、封装和可订购信息* 部分 30

Changes from Original (July 2013) to Revision A **Page**

- Added peak reflow and maximum number of reflows information 2
- 已更改 (corrected) typographical error. 19

10 器件和文档支持

10.1 器件支持

10.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

10.1.2 开发支持

10.1.2.1 使用 WEBENCH® 工具创建定制设计

单击此处，使用 LMZ31506H 器件并借助 WEBENCH® 电源设计器创建定制设计方案。

1. 首先键入输入电压 (V_{IN})、输出电压 (V_{OUT}) 和输出电流 (I_{OUT}) 要求。
2. 使用优化器拨盘优化关键参数设计，如效率、封装和成本。
3. 将生成的设计与德州仪器 (TI) 的其他解决方案进行比较。

WEBENCH 电源设计器可提供定制原理图以及罗列实时价格和组件供货情况的物料清单。

在多数情况下，可执行以下操作：

- 运行电气仿真，观察重要波形以及电路性能
- 运行热性能仿真，了解电路板热性能
- 将定制原理图和布局方案导出至常用 CAD 格式
- 打印设计方案的 PDF 报告并与同事共享

有关 WEBENCH 工具的详细信息，请访问 www.ti.com.cn/WEBENCH。

10.2 文档支持

10.2.1 相关文档

请参阅如下相关文档：

BQFN 封装的焊接要求

10.3 接收文档更新通知

要接收文档更新通知，请导航至 TI.com.cn 上的器件产品文件夹。单击右上角的*通知我* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

10.4 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商“按照原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 《使用条款》。

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设计支持 ***TI 参考设计支持*** **可帮助您快速查找有帮助的 E2E 论坛、设计支持工具以及技术支持的联系信息。**

10.5 商标

E2E is a trademark of Texas Instruments.
WEBENCH is a registered trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

10.6 静电放电警告

ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。 精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

10.7 术语表

SLYZ022 — *TI 术语表*。

这份术语表列出并解释术语、缩写和定义。

11 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请参阅左侧的导航栏。

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMZ31506HRUQR	ACTIVE	B1QFN	RUQ	47	500	RoHS Exempt & Green	NIPDAU	Level-3-245C-168 HR	-40 to 85	LMZ31506H	Samples
LMZ31506HRUQT	ACTIVE	B1QFN	RUQ	47	250	RoHS Exempt & Green	NIPDAU	Level-3-245C-168 HR	-40 to 85	LMZ31506H	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

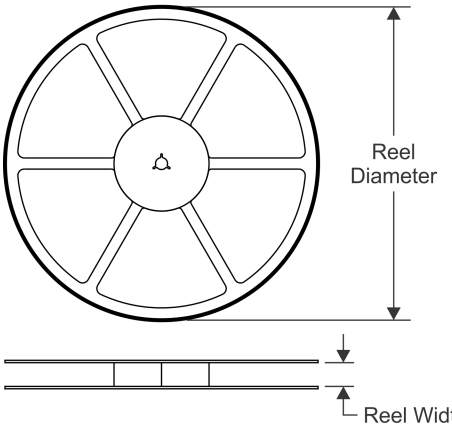
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

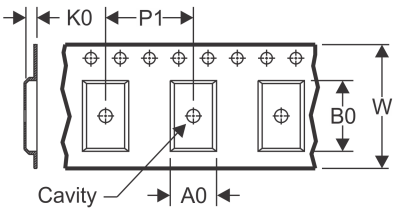
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

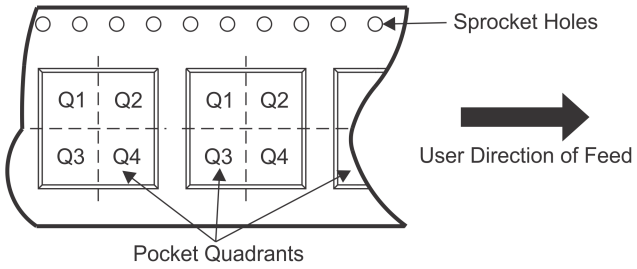


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

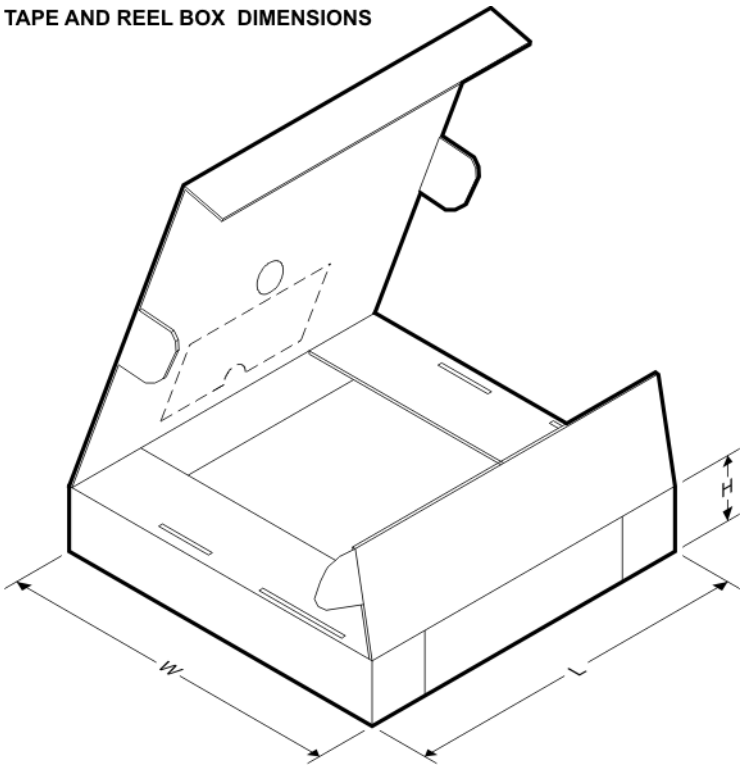
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMZ31506HRUQR	B1QFN	RUQ	47	500	330.0	24.4	9.35	15.35	3.1	16.0	24.0	Q1
LMZ31506HRUQT	B1QFN	RUQ	47	250	330.0	24.4	9.35	15.35	3.1	16.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

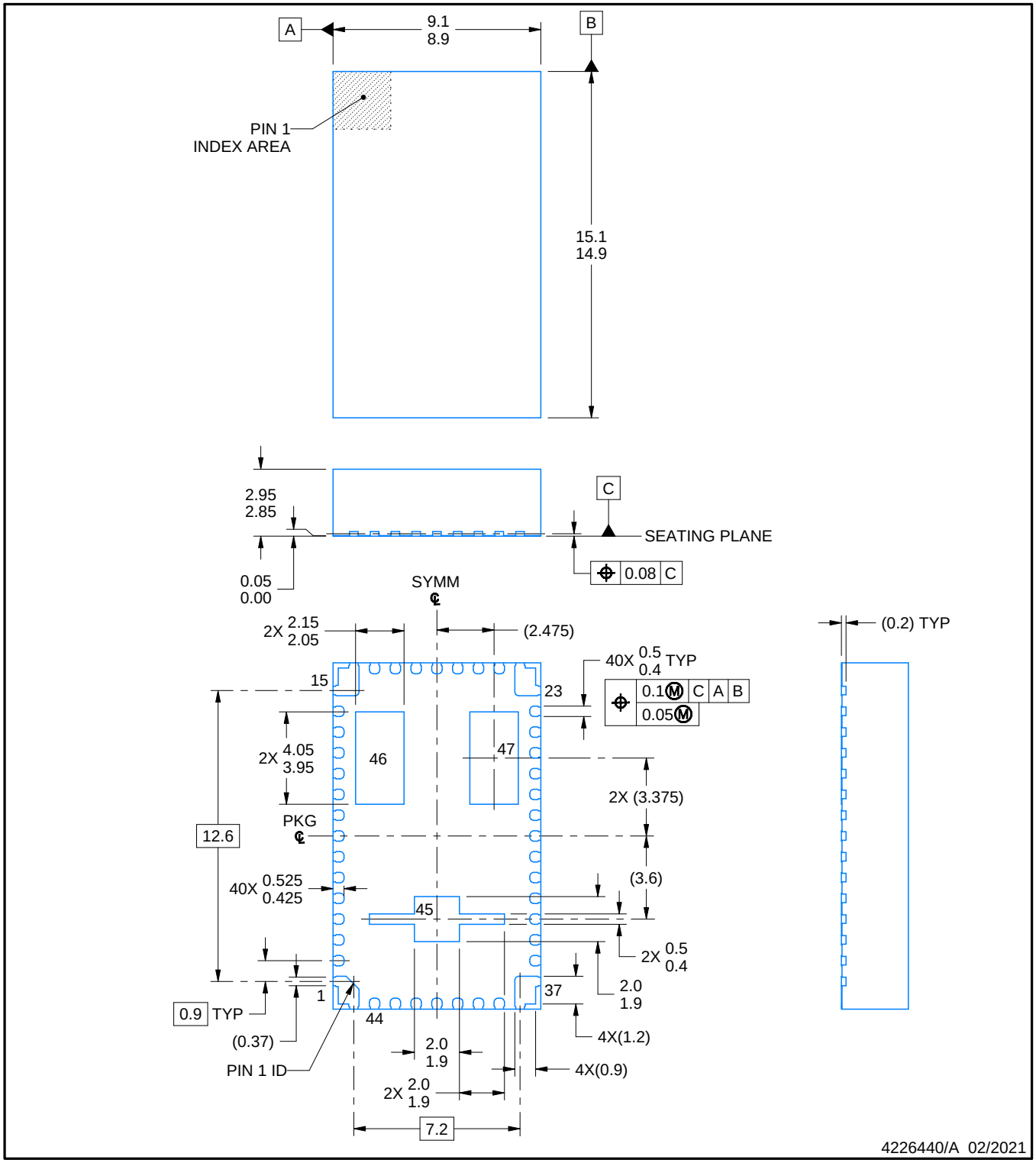
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMZ31506HRUQR	B1QFN	RUQ	47	500	383.0	353.0	58.0
LMZ31506HRUQT	B1QFN	RUQ	47	250	383.0	353.0	58.0

PACKAGE OUTLINE

RUQ0047A

B1QFN - 2.95 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

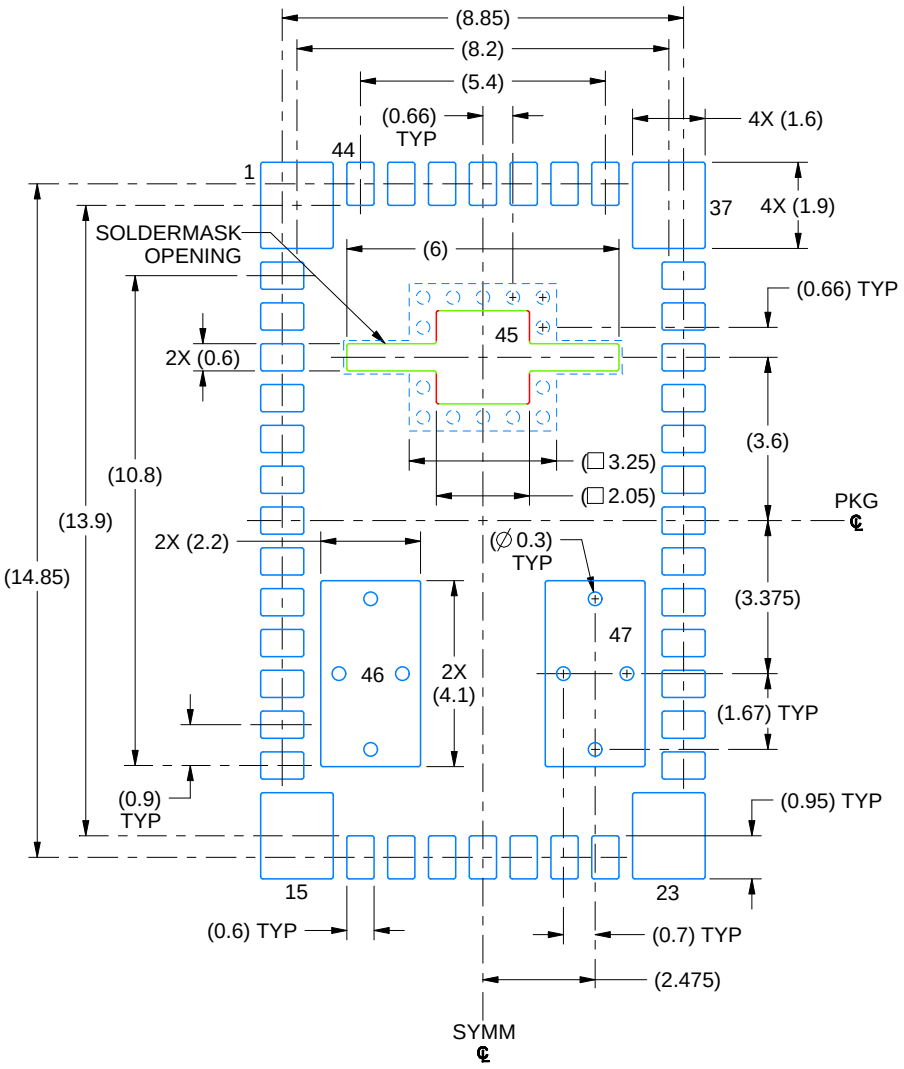
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pads must be soldered to the printed circuit board for optimal thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

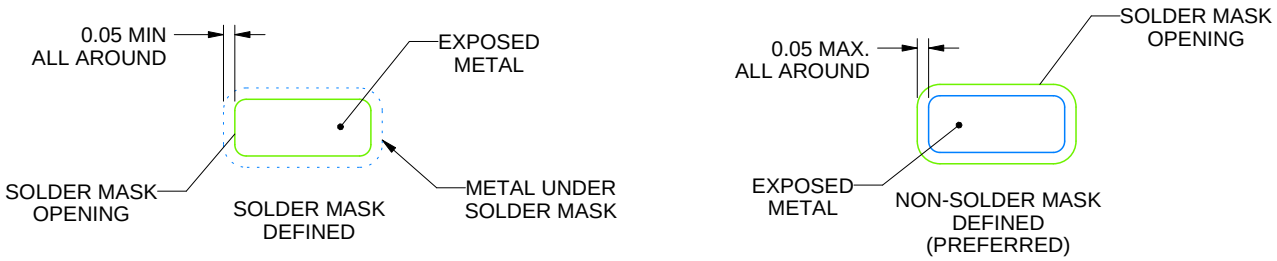
RUQ0047A

B1QFN - 2.95 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:6X

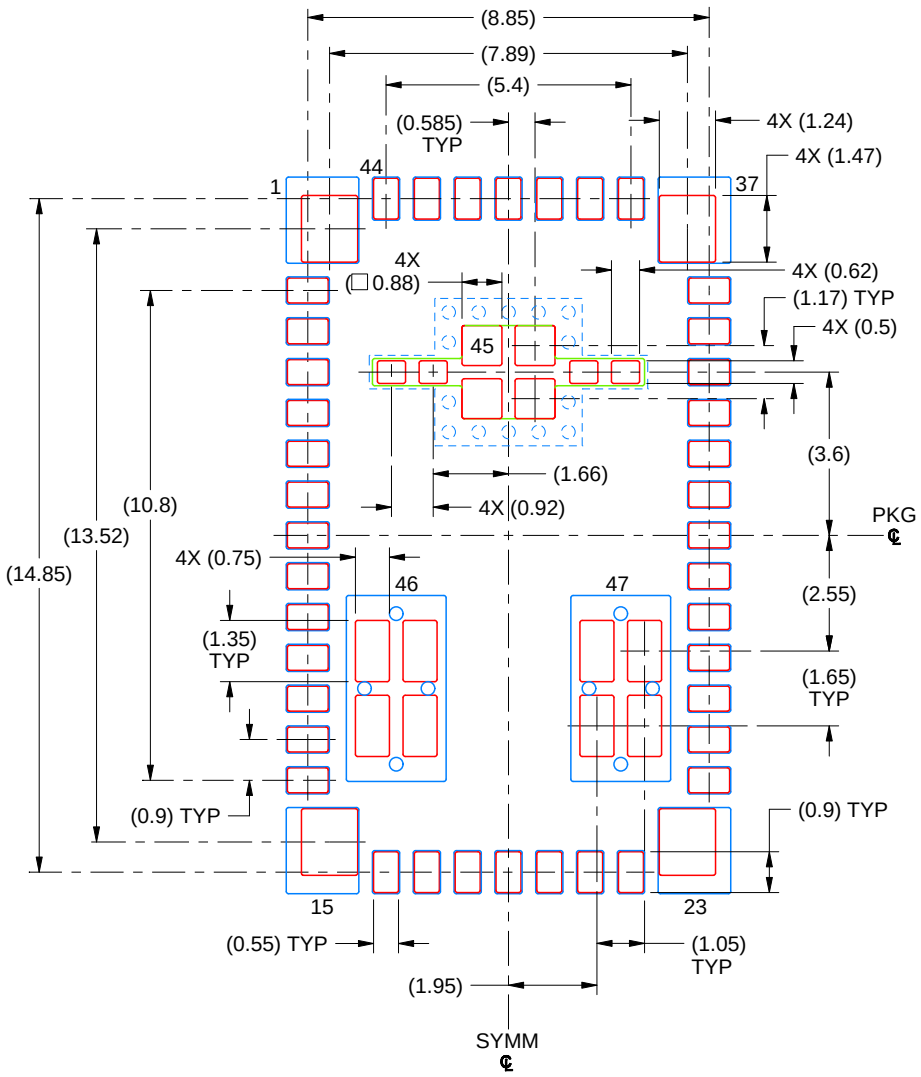


SOLDER MASK DETAIL

4226440/A 02/2021

NOTES: (continued)

4. This package designed to be soldered to a thermal pads on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm STENCIL THICKNESS

CORNER PINS 1, 15, 23 & 37:
60% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

EXPOSED PAD 45:
66% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

EXPOSED PAD 46 & 47:
45% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:6X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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